

TEST REPORT

FCC LTE Test for SM-T725
Certification

APPLICANT
SAMSUNG Electronics Co., Ltd.

REPORT NO.
HCT-RF-1906-FC015-R1

DATE OF ISSUE
17 June 2019

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TEST REPORT

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Other ID

FCC: A3LSMT725U

Applicant

SAMSUNG Electronics Co., Ltd.

129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16677, Rep. of Korea

Eut Type

Tablet

Model Name

SM-T725

Additional Model(s)

SM-T725N, SM-T727

Date of Receipt

May 10, 2019

FCC Rule Part(s)

§ 27, § 2

FCC Classification

PCS Licensed Transmitter (PCB)

Manufacturer

SAMSUNG Electronics Co., Ltd.

Tested by

Kwon Jeong

Technical Manager

Jong Seok Lee

HCT CO., LTD.

Soo Chan Lee
SooChan Lee / CEO

REVISION HISTORY

The revision history for this test report is shown in table.

Revision No.	Date of Issue	Description
0	June 10, 2019	Initial Release
1	June 17, 2019	Revised the date of test Revised the date of test equipment

The measurements shown in this report were made in accordance with the procedures specified in CFR47 section § 2.947. I assume full responsibility for the accuracy and completeness of these measurements, and for the qualifications of all persons taking them.

HCT CO., LTD. Certifies that no party to this application has subject to a denial of Federal benefits that includes FCC benefits pursuant to section 5301 of the Anti-Drug Abuse Act of 1998, 21 U.S. C. 853(a)

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MEASUREMENT REPORT**1. GENERAL INFORMATION**

Applicant Name:	SAMSUNG Electronics Co., Ltd.
Address:	129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16677, Rep. of Korea
FCC ID:	A3LSMT725U
Application Type:	Certification
FCC Classification:	PCS Licensed Transmitter (PCB)
FCC Rule Part(s):	§ 27, § 2
EUT Type:	Tablet
Model(s):	SM-T725
Additional Model(s):	T725N, T727
Keyboard Information	Model : EH-FT720 Manufacture: SAMSUNG
Charging Doc Information	Model : EE-D3200 Manufacture: SAMSUNG
Data Reuse	According to the Evaluation report, all of the data contained herein is reused from the reference FCC ID : A3LSMT725 report.
Tx Frequency:	699.7 MHz – 715.3 MHz (LTE – Band 12 (1.4 MHz)) 700.5 MHz – 714.5 MHz (LTE – Band 12 (3 MHz)) 701.5 MHz – 713.5 MHz (LTE – Band 12/17 (5 MHz)) 704.0 MHz – 711.0 MHz (LTE – Band 12/17 (10 MHz))
Date(s) of Tests:	March 04, 2019 ~ March 13, 2019

1.1. MAXIMUM OUTPUT POWER

Mode (MHz)	Tx Frequency (MHz)	Emission Designator	Modulation	ERP	
				Max. Power (W)	Max. Power (dBm)
LTE – Band12 (1.4)	699.7 – 715.3	1M09G7D	QPSK	0.037	15.73
		1M09W7D	16QAM	0.031	14.97
		1M09W7D	64QAM	0.025	13.99
LTE – Band12 (3)	700.5 – 714.5	2M71G7D	QPSK	0.038	15.78
		2M70W7D	16QAM	0.032	15.03
		2M71W7D	64QAM	0.025	14.05
LTE – Band12 / 17 (5)	701.5 – 713.5	4M51G7D	QPSK	0.038	15.77
		4M50W7D	16QAM	0.032	15.02
		4M50W7D	64QAM	0.025	14.04
LTE – Band12 / 17 (10)	704.0 – 711.0	8M98G7D	QPSK	0.036	15.53
		8M99W7D	16QAM	0.030	14.84
		9M00W7D	64QAM	0.024	13.81

2. INTRODUCTION

2.1. DESCRIPTION OF EUT

The EUT was a Tablet with GSM/GPRS/EGPRS/UMTS and LTE.

It also supports IEEE 802.11 a/b/g/n/ac (HT20/40/80), ANT+, Bluetooth, BT LE.

2.2. MEASURING INSTRUMENT CALIBRATION

The measuring equipment, which was utilized in performing the tests documented herein, has been calibrated in accordance with the manufacturer's recommendations for utilizing calibration equipment, which is traceable to recognized national standards.

2.3. TEST FACILITY

The Fully-anechoic chamber and conducted measurement facility used to collect the radiated data are located at the 74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, 17383, Rep. of KOREA.

3. DESCRIPTION OF TESTS

3.1 TEST PROCEDURE

Test Description	Test Procedure Used
Occupied Bandwidth	- KDB 971168 D01 v03r01 – Section 4.3 - ANSI C63.26-2015 – Section 5.4.4
Band Edge	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Spurious and Harmonic Emissions at Antenna Terminal	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Conducted Output Power	- N/A (See SAR Report)
Frequency stability	- ANSI C63.26-2015 – Section 5.6
Effective Radiated Power/ Effective Isotropic Radiated Power	- KDB 971168 D01 v03r01 – Section 5.2 & 5.8 - ANSI C63.26-2015 – Section 5.2 - ANSI/TIA-603-E-2016 – Section 2.2.17
Radiated Spurious and Harmonic Emissions	- KDB 971168 D01 v03r01 – Section 6.2 - ANSI/TIA-603-E-2016 – Section 2.2.12

3.2 RADIATED POWER

Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

The equipment under test is placed on a non-conductive table 3-meters away from the receive antenna in accordance with ANSI/TIA-603-E-2016 Clause 2.2.17.

Test Settings

1. Radiated power measurements are performed using the signal analyzer's "channel power" measurement capability for signals with continuous operation.
2. RBW = 1 – 5% of the expected OBW, not to exceed 1MHz
3. VBW $\geq 3 \times$ RBW
4. Span = 1.5 times the OBW
5. No. of sweep points $> 2 \times$ span / RBW
6. Detector = RMS
7. Trigger is set to "free run" for signals with continuous operation with the sweep times set to "auto".
8. The integration bandwidth was roughly set equal to the measured OBW of the signal for signals with continuous operation.
9. Trace mode = trace averaging (RMS) over 100 sweeps
10. The trace was allowed to stabilize

Test Note

1. The turntable is rotated through 360 degrees, and the receiving antenna scans in order to determine the level of the maximized emission.
2. A half wave dipole is then substituted in place of the EUT. For emissions above 1GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator and the previously recorded signal was duplicated.

The power is calculated by the following formula;

$$P_{d(dBm)} = P_{g(dBm)} - \text{cable loss}_{(dB)} + \text{antenna gain}_{(dB)}$$

Where: P_d is the dipole equivalent power and P_g is the generator output power into the substitution antenna.

3. The maximum value is calculated by adding the forward power to the calibrated source plus its appropriate gain

These steps are repeated with the receiving antenna in both vertical and horizontal polarization. the difference between the gain of the horn and an isotropic antenna are taken into consideration

4. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
5. All measurements are performed as RMS average measurements while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies.

3.3 RADIATED SPURIOUS EMISSIONS

Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

Radiated Spurious Emission Measurements at 3 meters by Substitution Method according to ANSI/TIA-603-E-2016.

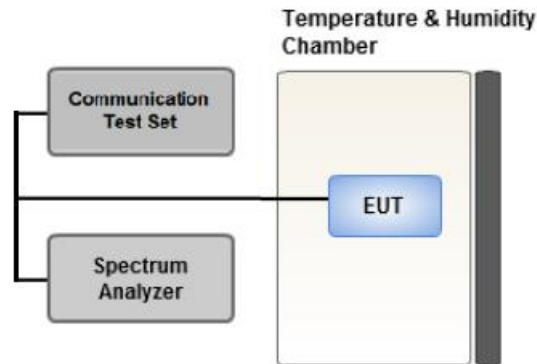
Test Settings

1. RBW = 100kHz for emissions below 1GHz and 1MHz for emissions above 1GHz
2. VBW $\geq 3 \times$ RBW
3. Span = 1.5 times the OBW
4. No. of sweep points $> 2 \times$ span / RBW
5. Detector = Peak
6. Trace mode = Max Hold
7. The trace was allowed to stabilize
8. Test channel : Low/ Middle/ High
9. Frequency range : We are performed all frequency to 10th harmonics from 9 kHz.

Test Note

1. Measurements value show only up to 3 maximum emissions noted, or would be lesser if no specific emissions from the EUT are recorded (ie: margin > 20 dB from the applicable limit) and considered that's already beyond the background noise floor.
2. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning. The worst case emissions are reported with the EUT positioning, modulations, RB sizes and offsets, and channel bandwidth configurations shown in the test data

3.4 OCCUPIED BANDWIDTH.



Test setup

The width of a frequency band such that, below the lower and above the upper frequency limits, the mean powers emitted are each equal to a specified percentage 0.5 % of the total mean power of a given emission.

The EUT makes a call to the communication simulator.

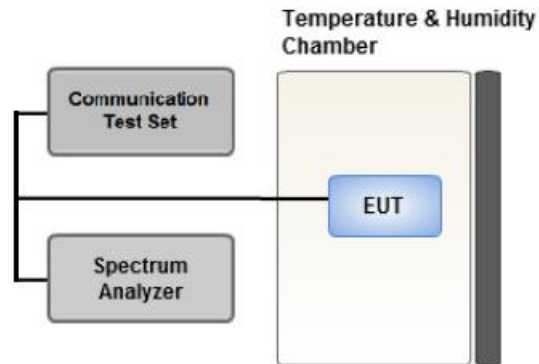
The conducted occupied bandwidth used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

The communication simulator station system controlled a EUT to export maximum output power under transmission mode and specific channel frequency. Use OBW measurement function of Spectrum analyzer to measure 99 % occupied bandwidth

Test Settings

1. The signal analyzer's automatic bandwidth measurement capability was used to perform the 99% occupied bandwidth and the 26dB bandwidth. The bandwidth measurement was not influenced by any intermediate power nulls in the fundamental emission.
2. RBW = 1 – 5% of the expected OBW
3. VBW $\geq 3 \times$ RBW
4. Detector = Peak
5. Trace mode = max hold
6. Sweep = auto couple
7. The trace was allowed to stabilize
8. If necessary, steps 2 – 7 were repeated after changing the RBW such that it would be within 1 – 5% of the 99% occupied bandwidth observed in Step 7

3.5 SPURIOUS AND HARMONIC EMISSIONS AT ANTENNA TERMINAL



Test setup

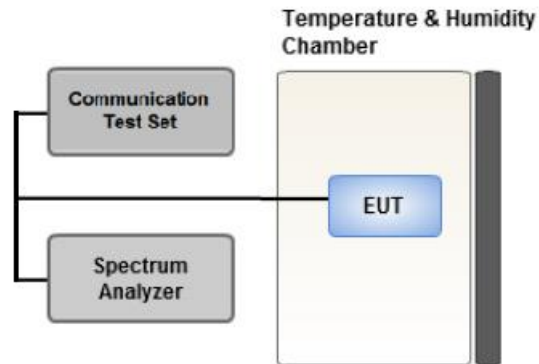
Test Overview

The level of the carrier and the various conducted spurious and harmonic frequencies is measured by means of a calibrated spectrum analyzer. The spectrum is scanned from the lowest frequency generated in the equipment up to a frequency including its 10th harmonic. All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

Test Settings

1. RBW = 1 MHz
2. VBW $\geq$ 3 MHz
3. Detector = RMS
4. Trace Mode = trace average
5. Sweep time = auto
6. Number of points in sweep $\geq 2 * \text{Span} / \text{RBW}$

3.6 BAND EDGE



Test setup

Test Overview

All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

Test Settings

1. Start and stop frequency were set such that the band edge would be placed in the center of the plot
2. Span was set large enough so as to capture all out of band emissions near the band edge
3. RBW > 1% of the emission bandwidth
4. VBW > 3 x RBW
5. Detector = RMS
6. Number of sweep points $\geq 2 \times \text{Span/RBW}$
7. Trace mode = trace average
8. Sweep time = auto couple
9. The trace was allowed to stabilize

Test Notes

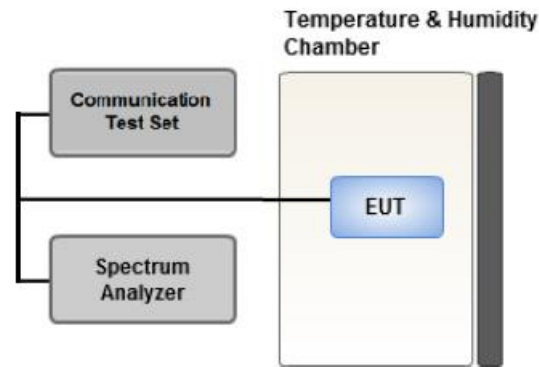
According to FCC 22.917, 24.238, 27.53 specified that power of any emission outside of The authorized operating frequency ranges must be attenuated below the transmitting power (P) by a factor of at least $43 + 10 \log(P)$ dB. In

MHz bands immediately outside and adjacent to the frequency block a resolution bandwidth of at least one percent of the emission bandwidth of the fundamental emission of the transmitter may be employed.

All measurements were done at 2 channels(low and high operational frequency range.)

The band edge measurement used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

3.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE



Test setup

Test Overview

Frequency stability testing is performed in accordance with the guidelines of ANSI C63.26-2015.

The frequency stability of the transmitter is measured by:

1. Temperature:

The temperature is varied from -30°C to +50°C in 10°C increments using an environmental chamber.

2. Primary Supply Voltage:

.- Unless otherwise specified, vary primary supply voltage from 85% to 115% of the nominal value for other than hand carried battery equipment.

.- For hand carried, battery powered equipment, reduce the primary ac or dc supply voltage to the battery operating end point, which shall be specified by the manufacturer.

Test Settings

1. The carrier frequency of the transmitter is measured at room temperature (20°C to provide a reference).
2. The equipment is turned on in a "standby" condition for fifteen minutes before applying power to the transmitter. Measurement of the carrier frequency of the transmitter is made within one minute after applying power to the transmitter.
3. Frequency measurements are made at 10°C intervals ranging from -30°C to +50°C. A period of at least one half-hour is provided to allow stabilization of the equipment at each temperature level.

3.8 WORST CASE(RADIATED TEST)

- The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
- All modes of operation were investigated and the worst case configuration results are reported.
- The worst case is reported with the EUT positioning, modulations, and paging service configurations shown in the test data.
- SM-T725 & additional models were tested and the worst case results are reported.
(Worst case : SM-T725)
- SM-T725 with Stand alone&Keyboard&Charging pad were tested and the worst case results are reported.
(Worst case : Stand alone)
- Please refer to the table below.
- LTE Band 12 (698 – 716 MHz, 5/10MHzbandwidth) overlaps the entire frequency range of LTE Band 17 (704 - 716 MHz) and they have the same Tune-up power.
Therefore, test data provided in this report covers Band 17 as well as Band 12.

[Worst case]

Test Description	Modulation	RB size	RB offset	Axis
Effective Radiated Power	QPSK, 16QAM, 64QAM	1	0	Z
Radiated Spurious and Harmonic Emissions	QPSK	1	0	Y

3.9 WORST CASE(CONDUCTED TEST)

- Worst case : Of all modulation, We have tested modulation of the high Conducted Output Power.

Conducted Output Power value can be confirmed on the SAR report.

- LTE Band 12 (698 – 716 MHz, 5/10MHzbandwidth) overlaps the entire frequency range of LTE Band 17 (704 - 716 MHz) and they have the same Tune-up power.

Therefore, test data provided in this report covers Band 17 as well as Band 12.

[Worst case]

Test Description	Modulation	Bandwidth (MHz)	Frequency	RB size	RB offset
Occupied Bandwidth	QPSK, 16QAM, 64QAM	1.4, 3, 5, 10	Mid	Full RB	0
Band Edge	* QPSK	1.4	Low	1	0
			High	1	5
		3	Low	1	0
			High	1	14
		5	Low	1	0
			High	1	24
		10	Low	1	0
			High	1	49
		1.4, 3, 5, 10	Low, High	Full RB	0
Spurious and Harmonic Emissions at Antenna Terminal	* QPSK	1.4, 3, 5, 10	Low, Mid, High	1	0

- All modes of operation were investigated and the worst case configuration results are reported.

- SM-T725 & additional models were tested and the worst case results are reported.

(Worst case : SM-T725)

OF TEST EQUIPMENT

Manufacture	Model/ Equipment	Serial Number	Calibration Date	Calibration Interval	Calibration Due
REOHDE & SCHWARZ	SCU 18 / AMPLIFIER	10094	04/17/2018	Annual	04/17/2019
Wainwright	WHK1.2/15G-10EF/H.P.F	4	04/04/2018	Annual	04/04/2019
Wainwright	WHK3.3/18G-10EF/H.P.F	2	04/04/2018	Annual	04/04/2019
Hewlett Packard	11667B / Power Splitter(DC~26.5 GHz)	5001	06/07/2018	Annual	06/07/2019
Agilent	E3632A/DC Power Supply	KR75303243	05/09/2018	Annual	05/09/2019
Schwarzbeck	UHAP/ Dipole Antenna	557	03/31/2017	Biennial	03/31/2019
Schwarzbeck	UHAP/ Dipole Antenna	558	03/31/2017	Biennial	03/31/2019
ESPEC	SU-642 / Chamber	93000718	08/07/2018	Annual	08/07/2019
Schwarzbeck	BBHA 9120D/ Horn Antenna(1~18GHz)	147	09/14/2018	Annual	09/14/2019
Schwarzbeck	BBHA 9120D/ Horn Antenna(1~18GHz)	9120D-1298	10/04/2018	Annual	10/04/2019
Schwarzbeck	BBHA 9170/ Horn Antenna(15~40GHz)	BBHA9170342	04/25/2017	Biennial	04/25/2019
Schwarzbeck	BBHA 9170/ Horn Antenna(15~40GHz)	BBHA9170124	04/25/2017	Biennial	04/25/2019
Agilent	N9020A/Signal Analyzer(10Hz~26.5GHz)	MY52090906	06/08/2018	Annual	06/08/2019
Hewlett Packard	8493C/ATTENUATOR(20dB)	17280	06/21/2018	Annual	06/21/2019
REOHDE & SCHWARZ	FSV40/Spectrum Analyzer(10Hz~40GHz)	100931	10/22/2018	Annual	10/22/2019
Agilent	8960 (E5515C)/ Base Station	MY48360800	09/27/2018	Annual	09/27/2019
Schwarzbeck	FMZB1513/ Loop Antenna(9kHz~30MHz)	1513-175	08/23/2018	Biennial	08/23/2020
Schwarzbeck	VULB9160/ Bilog Antenna	9160-3368	08/09/2018	Biennial	08/09/2020
Schwarzbeck	VULB9160/ Hybrid Antenna	760	04/06/2017	Biennial	04/06/2019
Anritsu Corp.	MT8821C/Wideband Radio Communication Tester	6201502997	08/13/2018	Annual	08/13/2019
Anritsu Corp.	MT8820C/Wideband Radio Communication Tester	6201026545	01/30/2019	Annual	01/30/2020
REOHDE & SCHWARZ	SMB100A/ SIGNAL GENERATOR (100kHz~40GHz)	177633	07/19/2018	Annual	07/19/2019
REOHDE & SCHWARZ	ESU40 / EMI TEST RECEIVER	100524	07/27/2018	Annual	07/27/2019
HCT CO., LTD.,	FCC LTE Mobile Conducted RF Automation Test Software	-	-	-	-

Note:

1. Equipment listed above that has a calibration due date during the testing period, the testing is completed before equipment expiration date.

5. MEASUREMENT UNCERTAINTY

The measurement uncertainties shown below were calculated in accordance with the requirements of ANSI C63.4:2014.

All measurement uncertainty values are shown with a coverage factor of $k=2$ to indicate a 95 % level of confidence. The measurement data shown herein meets or exceeds the U_{CISPR} measurement uncertainty values specified in CISPR 16-4-2 and, thus, can be compared directly to specified limits to determine compliance.

Parameter	E
Conducted Disturbance (150 kHz ~ 30 MHz)	1.82
Radiated Disturbance (9 kHz ~ 30 MHz)	3.40
Radiated Disturbance (30 MHz ~ 1 GHz)	4.80
Radiated Disturbance (1 GHz ~ 18 GHz)	5.70
Radiated Disturbance (18 GHz ~ 40 GHz)	5.71

6. SUMMARY OF TEST RESULTS

6.1 Test Condition : Conducted Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Occupied Bandwidth	§ 2.1049	N/A	PASS
Band Edge / Spurious and Harmonic Emissions at Antenna Terminal.	§ 2.1051, § 27.53(g)	$< 43 + 10\log_{10} (P[\text{Watts}])$ at Band Edge and for all out-of-band emissions	PASS
Conducted Output Power	§ 2.1046	N/A	<u>See Note1</u>
Frequency stability / variation of ambient temperature	§ 2.1055, § 27.54	Emission must remain in band	PASS

Note:

1. See SAR Report
2. The same samples were used for SAR and EMC

6.2 Test Condition : Radiated Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Effective Radiated Power	§ 27.50(c)(10)	< 3 Watts max. ERP	PASS
Radiated Spurious and Harmonic Emissions	§ 2.1053, § 27.53(g)	$< 43 + 10\log_{10} (P[\text{Watts}])$ for all out-of band emissions	PASS

7. SAMPLE CALCULATION

7.1 ERP Sample Calculation

Ch./ Freq.		Measured Level(dBm)	Substitute Level(dBm)	Ant. Gain (dBd)	C.L	Pol.	ERP	
channel	Freq.(MHz)						W	dBm
128	824.20	-21.37	38.40	-10.61	0.95	H	0.483	26.84

$$\text{ERP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test , the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of effective radiated power.

7.2 EIRP Sample Calculation

Ch./ Freq.		Measured Level(dBm)	Substitute Level(dBm)	Ant. Gain (dBi)	C.L	Pol.	EIRP	
channel	Freq.(MHz)						W	dBm
20175	1,732.50	-15.75	18.45	9.90	1.76	H	0.456	26.59

$$\text{EIRP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test , the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of equivalent isotropic radiated power.

7.3. Emission Designator

GSM Emission Designator

Emission Designator = 249KGXW
GSM BW = 249 kHz
G = Phase Modulation
X = Cases not otherwise covered
W = Combination (Audio/Data)

WCDMA Emission Designator

Emission Designator = 4M17F9W
WCDMA BW = 4.17 MHz
F = Frequency Modulation
9 = Composite Digital Info
W = Combination (Audio/Data)

16QAM Modulation

Emission Designator = 4M48W7D
LTE BW = 4.48 MHz
W = Amplitude/Angle Modulated
7 = Quantized/Digital Info
D = Data transmission; telemetry; telecommand

EDGE Emission Designator

Emission Designator = 249KG7W
GSM BW = 249 kHz
G = Phase Modulation
7 = Quantized/Digital Info
W = Combination (Audio/Data)

QPSK Modulation

Emission Designator = 4M48G7D
LTE BW = 4.48 MHz
G = Phase Modulation
7 = Quantized/Digital Info
D = Data transmission; telemetry; telecommand

64QAM Modulation

Emission Designator = 4M48W7D
LTE BW = 4.48 MHz
W = Amplitude/Angle Modulated
7 = Quantized/Digital Info
D = Data transmission; telemetry; telecommand

8. TEST DATA

8.1 EFFECTIVE RADIATED POWER

Freq (MHz)	Mod (Bandwidth)	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBd)	C.L	Pol	Limit	ERP	
								W	W	dBm
699.7	LTE B12 (1.4 MHz)	QPSK	-31.44	25.91	-10.16	0.78	V	< 3.00	0.031	14.97
		16-QAM	-32.19	25.16	-10.16	0.78	V		0.026	14.22
		64-QAM	-33.17	24.18	-10.16	0.78	H		0.021	13.24
707.5		QPSK	-30.74	26.55	-10.17	0.78	V		0.036	15.60
		16-QAM	-31.47	25.82	-10.17	0.78	V		0.031	14.87
		64-QAM	-32.45	24.84	-10.17	0.78	H		0.024	13.89
715.3		QPSK	-30.52	26.69	-10.18	0.78	V		0.037	15.73
		16-QAM	-31.28	25.93	-10.18	0.78	V		0.031	14.97
		64-QAM	-32.26	24.95	-10.18	0.78	H		0.025	13.99

Freq (MHz)	Mod (Bandwidth)	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBd)	C.L	Pol	Limit	ERP	
								W	W	dBm
700.5	LTE B12 (3 MHz)	QPSK	-31.37	26.00	-10.16	0.78	V	< 3.00	0.032	15.06
		16-QAM	-32.13	25.24	-10.16	0.78	V		0.027	14.30
		64-QAM	-33.12	24.25	-10.16	0.78	H		0.021	13.31
707.5		QPSK	-30.75	26.54	-10.17	0.78	V		0.036	15.59
		16-QAM	-31.45	25.84	-10.17	0.78	V		0.031	14.89
		64-QAM	-32.45	24.84	-10.17	0.78	H		0.024	13.89
714.5		QPSK	-30.45	26.74	-10.18	0.78	V		0.038	15.78
		16-QAM	-31.20	25.99	-10.18	0.78	V		0.032	15.03
		64-QAM	-32.18	25.01	-10.18	0.78	H		0.025	14.05

Freq (MHz)	Mod (Bandwidth)	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBd)	C.L	Pol	Limit	ERP	
								W	W	dBm
701.5	LTE B12/17 (5 MHz)	QPSK	-31.34	26.06	-10.16	0.78	V	< 3.00	0.033	15.12
		16-QAM	-32.10	25.30	-10.16	0.78	V		0.027	14.36
		64-QAM	-33.08	24.32	-10.16	0.78	H		0.022	13.38
707.5		QPSK	-30.72	26.57	-10.17	0.78	V		0.036	15.62
		16-QAM	-31.43	25.86	-10.17	0.78	V		0.031	14.91
		64-QAM	-32.41	24.88	-10.17	0.78	H		0.025	13.93
713.5		QPSK	-30.45	26.73	-10.18	0.78	V		0.038	15.77
		16-QAM	-31.20	25.98	-10.18	0.78	V		0.032	15.02
		64-QAM	-32.18	25.00	-10.18	0.78	H		0.025	14.04

Freq (MHz)	Mod (Bandwidth)	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBd)	C.L	Pol	Limit	ERP	
								W	W	dBm
704.0	LTE B12/17 (10 MHz)	QPSK	-31.35	26.05	-10.16	0.78	V	< 3.00	0.032	15.11
		16-QAM	-32.10	25.30	-10.16	0.78	V		0.027	14.36
		64-QAM	-33.09	24.31	-10.16	0.78	H		0.022	13.37
707.5		QPSK	-30.94	26.35	-10.17	0.78	V		0.035	15.40
		16-QAM	-31.70	25.59	-10.17	0.78	V		0.029	14.64
		64-QAM	-32.69	24.60	-10.17	0.78	H		0.023	13.65
711.0		QPSK	-30.73	26.49	-10.18	0.78	V		0.036	15.53
		16-QAM	-31.42	25.80	-10.18	0.78	V		0.030	14.84
		64-QAM	-32.45	24.77	-10.18	0.78	H		0.024	13.81

8.3 RADIATED SPURIOUS EMISSIONS

- ▣ OPERATING FREQUENCY: 715.30 MHz
- ▣ MEASURED OUTPUT POWER: 15.73 dBm = 0.037 W
- ▣ MODE: LTE B12
- ▣ MODULATION SIGNAL: 1.4 MHz QPSK
- ▣ DISTANCE: 3 meters
- ▣ LIMIT: $43 + 10 \log_{10}(W) =$ 28.73 dBc

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBd)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	dBc
23017 (699.7)	1,399.40	-57.80	5.32	-64.36	1.16	H	-62.35	78.08
	2,099.10	-57.86	7.68	-64.35	1.44	H	-60.26	75.99
	2,798.80	-55.56	9.00	-60.64	1.72	H	-55.51	71.24
23095 (707.5)	1,415.00	-57.84	5.41	-64.26	1.17	V	-62.17	77.89
	2,122.50	-57.34	7.58	-63.25	1.46	V	-59.28	75.00
	2,830.00	-54.61	9.08	-59.82	1.72	H	-54.61	70.33
23173 (715.3)	1,430.60	-58.07	5.55	-64.96	1.17	V	-62.73	78.46
	2,145.90	-58.08	7.32	-63.34	1.47	H	-59.64	75.37
	2,861.20	-55.29	9.16	-60.28	1.74	H	-55.01	70.74

- ▣ OPERATING FREQUENCY: 714.50 MHz
- ▣ MEASURED OUTPUT POWER: 15.78 dBm = 0.038 W
- ▣ MODE: LTE B12
- ▣ MODULATION SIGNAL: 3 MHz QPSK
- ▣ DISTANCE: 3 meters
- ▣ LIMIT: $43 + 10 \log_{10}(W) =$ 28.78 dBc

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBd)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	dBc
23025 (700.5)	1,401.00	-58.27	5.32	-64.83	1.16	H	-62.82	78.60
	2,101.50	-57.36	7.68	-63.85	1.44	H	-59.76	75.54
	2,802.00	-55.34	9.00	-60.42	1.72	H	-55.29	71.07
23095 (707.5)	1,415.00	-57.99	5.41	-64.41	1.17	H	-62.32	78.09
	2,122.50	-57.56	7.58	-63.47	1.46	H	-59.50	75.28
	2,830.00	-56.64	9.08	-61.85	1.72	H	-56.64	72.41
23165 (714.5)	1,429.00	-58.45	5.55	-65.34	1.17	H	-63.11	78.89
	2,143.50	-57.57	7.32	-62.83	1.47	H	-59.13	74.91
	2,858.00	-55.10	9.16	-60.09	1.74	H	-54.82	70.60

- ▣ OPERATING FREQUENCY: 713.50 MHz
- ▣ MEASURED OUTPUT POWER: 15.77 dBm = 0.038 W
- ▣ MODE: LTE B12 / B17
- ▣ MODULATION SIGNAL: 5 MHz QPSK
- ▣ DISTANCE: 3 meters
- ▣ LIMIT: $43 + 10 \log_{10} (W) =$ 28.77 dBc

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBd)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	dBc
23035 (701.5)	1,403.00	-57.48	5.32	-64.04	1.16	H	-62.03	77.80
	2,104.50	-57.37	7.66	-63.60	1.45	H	-59.54	75.31
	2,806.00	-56.41	9.01	-61.49	1.70	H	-56.33	72.10
23095 (707.5)	1,415.00	-57.33	5.41	-63.75	1.17	H	-61.66	77.42
	2,122.50	-58.16	7.58	-64.07	1.46	H	-60.10	75.87
	2,830.00	-56.69	9.08	-61.90	1.72	H	-56.69	72.46
23155 (713.5)	$\equiv$	-58.64	5.55	-65.53	1.17	H	-63.30	79.07
	2,140.50	-56.93	7.37	-62.18	1.47	H	-58.43	74.20
	2,854.00	-53.70	9.16	-58.77	1.73	H	-53.49	69.26

- ▣ OPERATING FREQUENCY: 711.00 MHz
- ▣ MEASURED OUTPUT POWER: 15.53 dBm = 0.036 W
- ▣ MODE: LTE B12 / B17
- ▣ MODULATION SIGNAL: 10 MHz QPSK
- ▣ DISTANCE: 3 meters
- ▣ LIMIT: $43 + 10 \log_{10}(W) =$ 28.53 dBc

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBd)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	dBc
23060 (704.0)	1,408.00	-58.51	5.38	-64.84	1.17	H	-62.78	78.31
	2,112.00	-57.99	7.63	-63.96	1.45	H	-59.93	75.46
	2,816.00	-55.38	9.03	-60.58	1.70	H	-55.40	70.92
23095 (707.5)	1,415.00	-58.03	5.41	-64.45	1.17	H	-62.36	77.88
	2,122.50	-57.52	7.58	-63.43	1.46	H	-59.46	74.99
	2,830.00	-56.74	9.08	-61.95	1.72	H	-56.74	72.26
23130 (711.0)	1,422.00	-58.23	5.44	-64.73	1.17	H	-62.61	78.13
	2,133.00	-57.32	7.47	-63.07	1.47	H	-59.22	74.74
	2,844.00	-56.29	9.13	-61.43	1.71	H	-56.16	71.69

8.3 OCCUPIED BANDWIDTH

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (MHz)
12	1.4 MHz	707.5	QPSK	6	0	1.0929
			16-QAM			1.0909
			64-QAM			1.0913
	3 MHz		QPSK	15		2.7127
			16-QAM			2.6969
			64-QAM			2.7130
12/ 17	5 MHz		QPSK	25		4.5123
			16-QAM			4.5035
			64-QAM			4.4960
	10 MHz	QPSK	50	8.9831		
		16-QAM		8.9915		
		64-QAM		8.9957		

Note:

1. Plots of the EUT's Occupied Bandwidth are shown Page 45 ~ 56.

8.4 CONDUCTED SPURIOUS EMISSIONS

Band	Band Width (MHz)	Frequency (MHz)	Frequency of Maximum Harmonic (GHz)	Factor (dB)	Measurement Maximum Data (dBm)	Result (dBm)	Limit (dBm)
12	1.4	699.7	3.6970	27.976	-67.371	-39.395	-13.00
		707.5	3.6780	27.976	-67.183	-39.207	
		715.3	3.7000	27.976	-67.247	-39.271	
	3	700.5	3.7015	27.976	-67.244	-39.268	
		707.5	3.7034	27.976	-67.044	-39.068	
		714.5	3.7069	27.976	-67.396	-39.420	
12/17	5	701.5	3.7049	27.976	-67.075	-39.099	
		707.5	3.7219	27.976	-67.022	-39.046	
		713.5	3.6975	27.976	-67.260	-39.284	
	10	704.0	3.7149	27.976	-67.160	-39.184	
		707.5	3.6935	27.976	-67.286	-39.310	
		711.0	3.7119	27.976	-66.927	-38.951	

Note:

1. Plots of the EUT's Conducted Spurious Emissions are shown Page 82 ~ 93.
2. Conducted Spurious Emissions was Tested QPSK Modulation, Resource Block Size 1 and Resource Block Offset 0
3. Result (dBm) = Measurement Maximum Data (dBm) + Factor (dB)
4. Factor(dB) = Cable Loss + Attenuator + Power Splitter

Frequency Range (GHz)	Factor [dB]
0.03 – 1	25.270
1 – 5	27.976
5 – 10	28.591
10 – 15	29.116
15 – 20	29.489
Above 20	30.131

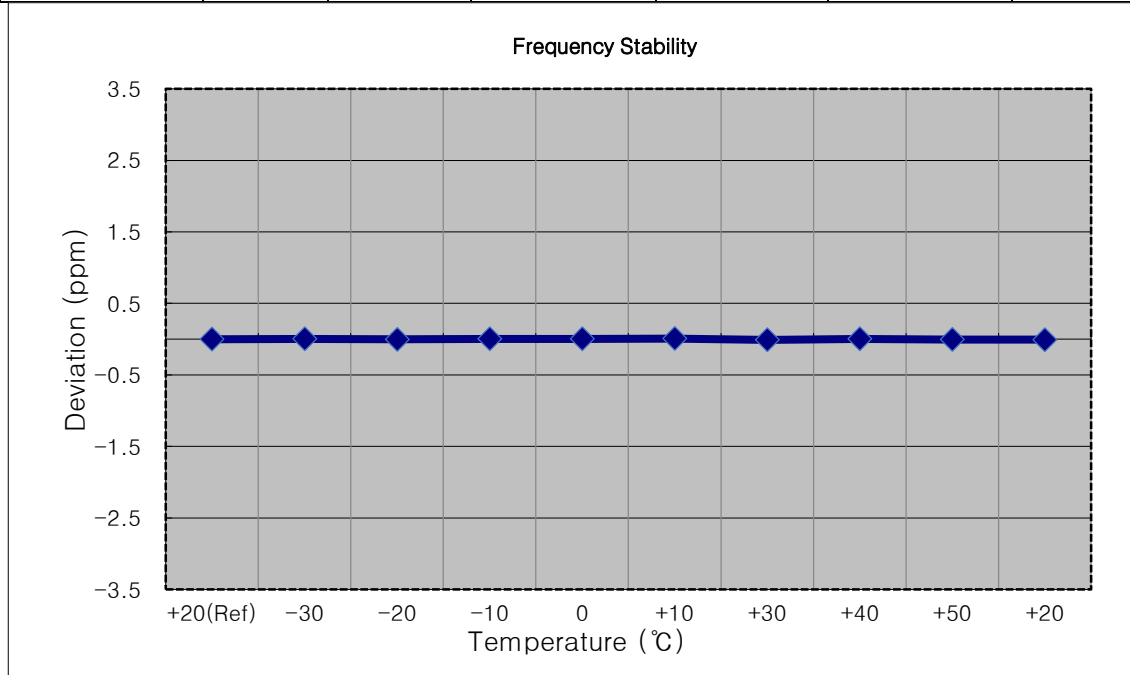
8.5 BAND EDGE

- Plots of the EUT's Band Edge are shown Page 57 ~ 81.

8.6 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE

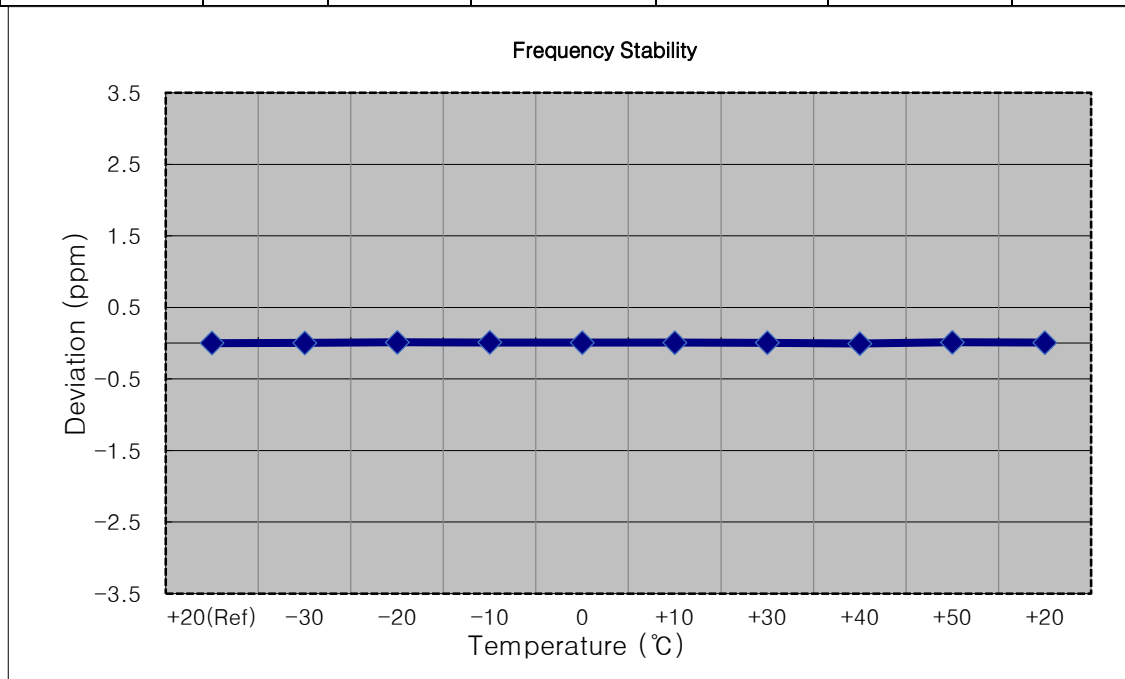
- MODE: LTE B12
- OPERATING FREQUENCY: 699,700,000 Hz
- CHANNEL: 23017 (1.4 MHz)
- REFERENCE VOLTAGE: 3.85 VDC
- DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	699 699 994	0.0	0.000 000	0.000
100%		-30	699 699 997	3.0	0.000 000	0.004
100%		-20	699 699 992	-1.8	0.000 000	-0.003
100%		-10	699 699 997	2.9	0.000 000	0.004
100%		0	699 699 997	3.1	0.000 000	0.004
100%		+10	699 700 000	5.6	0.000 001	0.008
100%		+30	699 699 987	-6.8	-0.000 001	-0.010
100%		+40	699 699 997	2.6	0.000 000	0.004
100%		+50	699 699 991	-2.9	0.000 000	-0.004
Batt. Endpoint	3.400	+20	699 699 989	-5.3	-0.000 001	-0.008



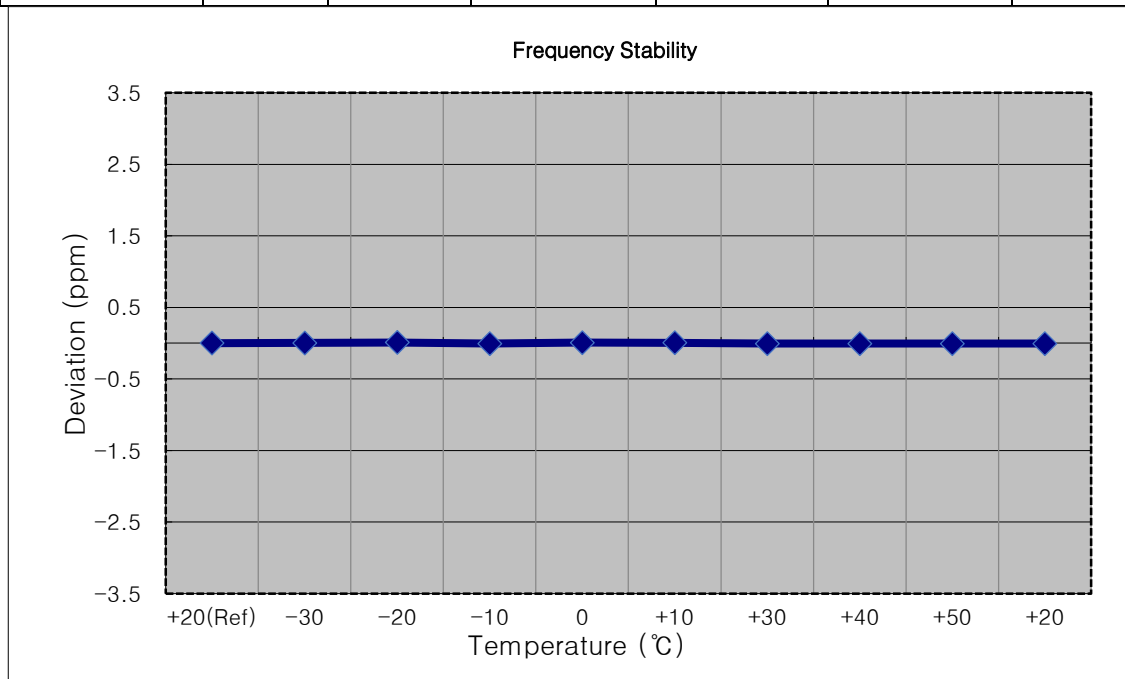
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 700,500,000 Hz
- ▣ CHANNEL: 23025 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.85 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	700 500 004	0.0	0.000 000	0.000
100%		-30	700 500 006	1.7	0.000 000	0.002
100%		-20	700 500 011	7.5	0.000 001	0.011
100%		-10	700 500 010	5.9	0.000 001	0.008
100%		0	700 500 009	5.2	0.000 001	0.007
100%		+10	700 500 008	4.5	0.000 001	0.006
100%		+30	700 500 007	2.7	0.000 000	0.004
100%		+40	700 500 000	-4.3	-0.000 001	-0.006
100%		+50	700 500 011	7.3	0.000 001	0.010
Batt. Endpoint	3.400	+20	700 500 009	4.7	0.000 001	0.007



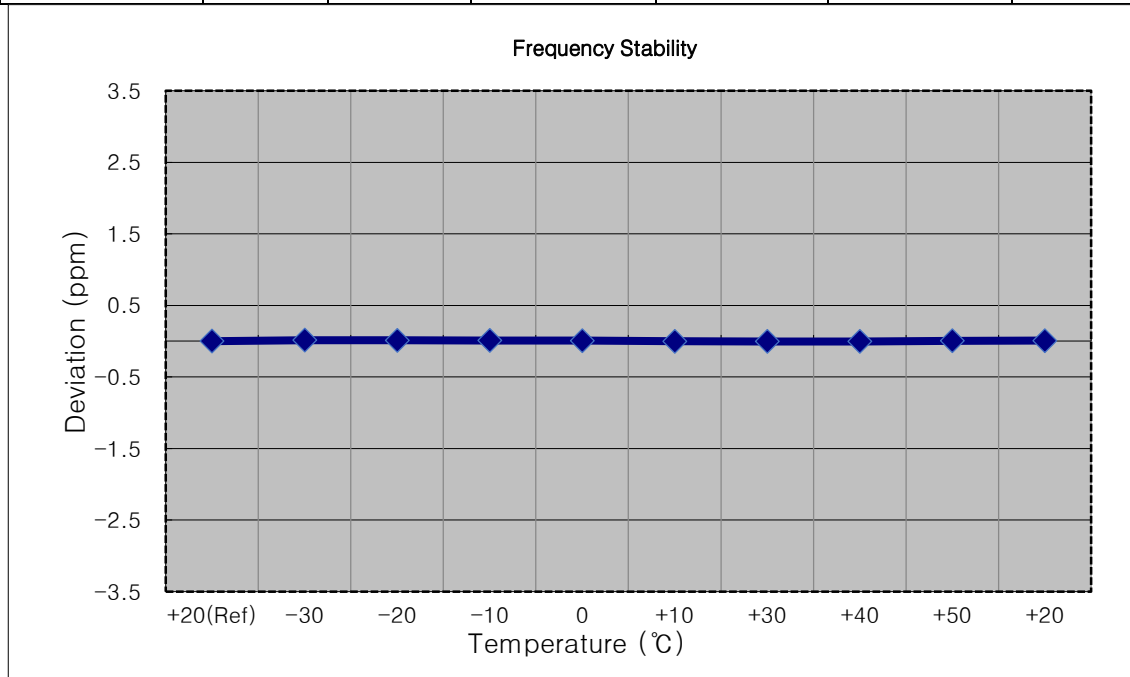
- ▣ MODE: LTE B12/17
- ▣ OPERATING FREQUENCY: 701,500,000 Hz
- ▣ CHANNEL: 23035 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.85 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	701 500 005	0.0	0.000 000	0.000
100%		-30	701 500 007	1.7	0.000 000	0.002
100%		-20	701 500 012	6.4	0.000 001	0.009
100%		-10	701 500 001	-3.7	-0.000 001	-0.005
100%		0	701 500 010	4.8	0.000 001	0.007
100%		+10	701 500 008	2.7	0.000 000	0.004
100%		+30	701 500 001	-4.4	-0.000 001	-0.006
100%		+40	701 500 001	-4.6	-0.000 001	-0.007
100%		+50	701 500 000	-4.7	-0.000 001	-0.007
Batt. Endpoint	3.400	+20	701 500 001	-3.7	-0.000 001	-0.005



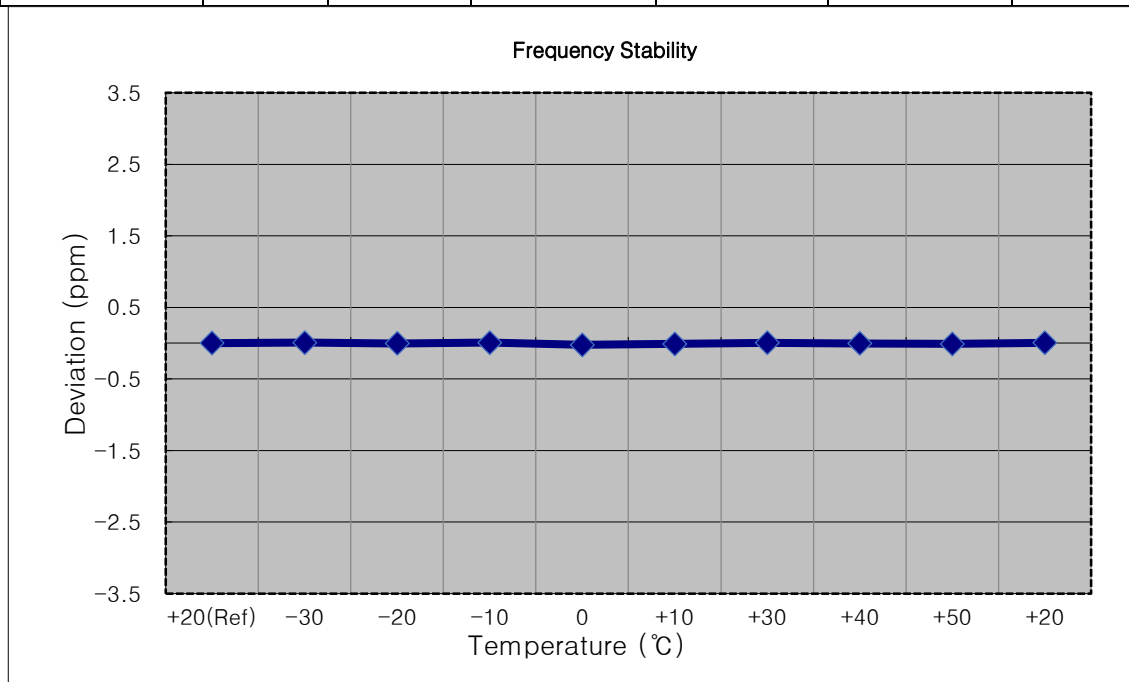
- ▣ MODE: LTE B12/17
- ▣ OPERATING FREQUENCY: 704,000,000 Hz
- ▣ CHANNEL: 23060 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.85 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	704 000 010	0.0	0.000 000	0.000
100%		-30	704 000 020	9.6	0.000 001	0.014
100%		-20	704 000 019	8.6	0.000 001	0.012
100%		-10	704 000 016	5.8	0.000 001	0.008
100%		0	704 000 015	4.7	0.000 001	0.007
100%		+10	704 000 008	-2.0	0.000 000	-0.003
100%		+30	704 000 007	-2.9	0.000 000	-0.004
100%		+40	704 000 008	-2.6	0.000 000	-0.004
100%		+50	704 000 014	3.4	0.000 000	0.005
Batt. Endpoint	3.400	+20	704 000 015	4.3	0.000 001	0.006



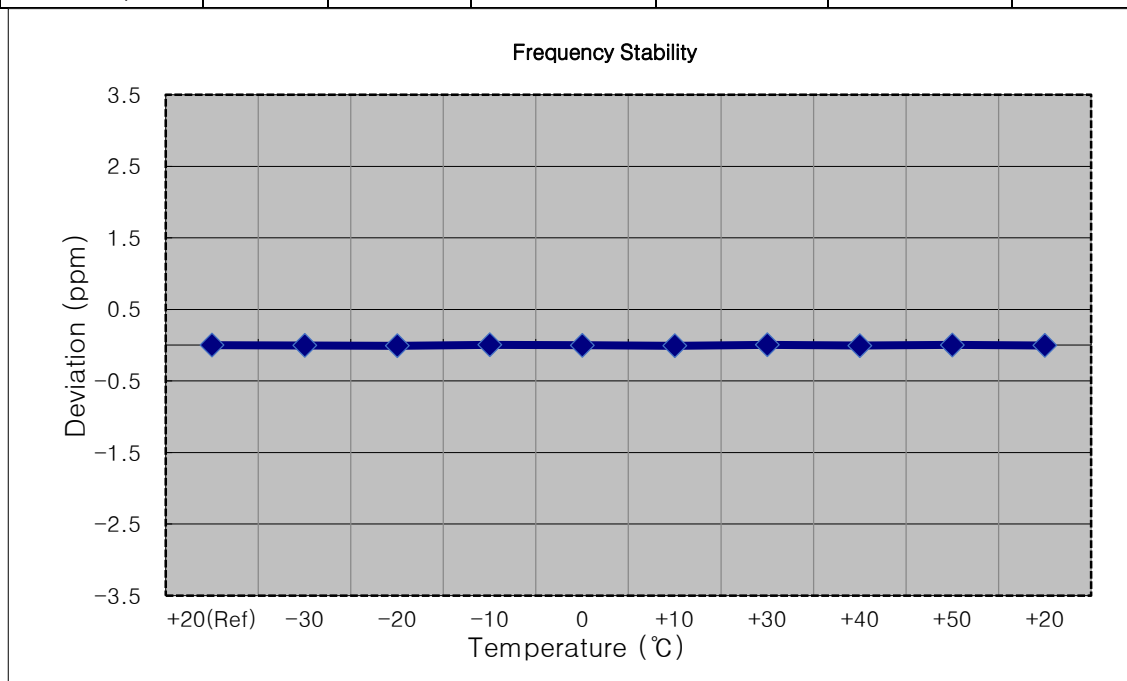
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 707,500,000 Hz
- ▣ CHANNEL: 23095 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 3.85 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	707 500 002	0.0	0.000 000	0.000
100%		-30	707 500 008	5.1	0.000 001	0.007
100%		-20	707 499 999	-3.7	-0.000 001	-0.005
100%		-10	707 500 007	4.5	0.000 001	0.006
100%		0	707 499 985	-17.0	-0.000 002	-0.024
100%		+10	707 499 995	-7.0	-0.000 001	-0.010
100%		+30	707 500 006	4.0	0.000 001	0.006
100%		+40	707 500 000	-2.8	0.000 000	-0.004
100%		+50	707 499 996	-6.9	-0.000 001	-0.010
Batt. Endpoint	3.400	+20	707 500 005	2.8	0.000 000	0.004



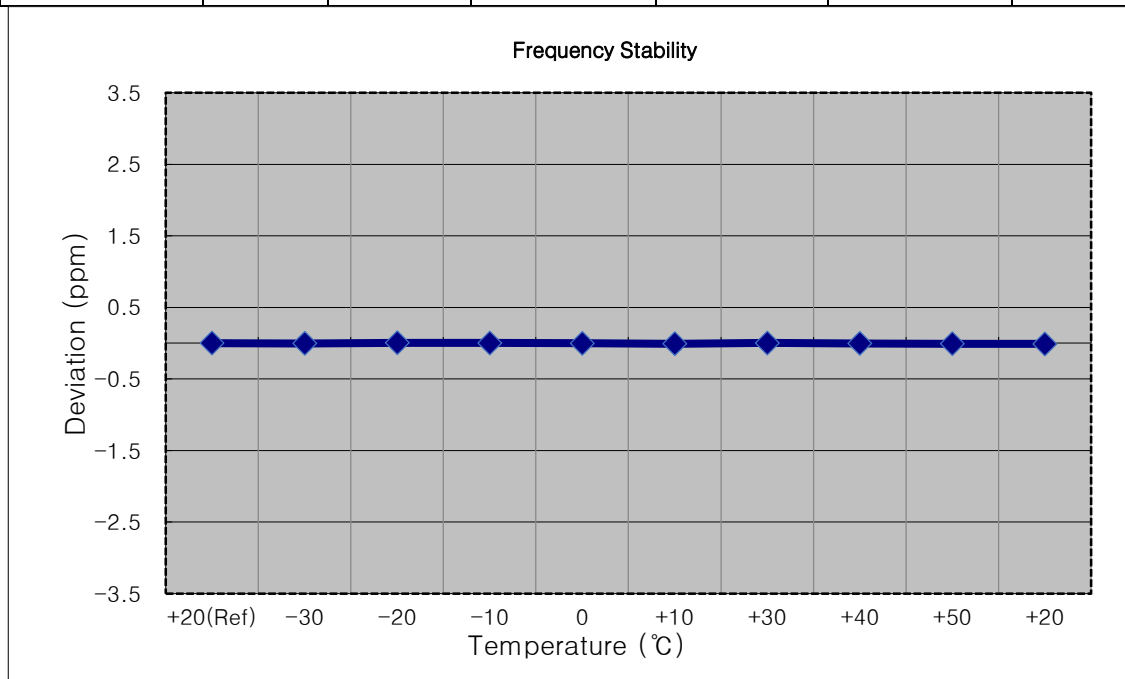
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 707,500,000 Hz
- ▣ CHANNEL: 23095 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.85 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	707 499 995	0.0	0.000 000	0.000
100%		-30	707 499 992	-2.5	0.000 000	-0.004
100%		-20	707 499 989	-5.8	-0.000 001	-0.008
100%		-10	707 499 998	3.7	0.000 001	0.005
100%		0	707 499 993	-2.1	0.000 000	-0.003
100%		+10	707 499 989	-5.8	-0.000 001	-0.008
100%		+30	707 499 998	3.0	0.000 000	0.004
100%		+40	707 499 990	-4.8	-0.000 001	-0.007
100%		+50	707 499 997	2.5	0.000 000	0.004
Batt. Endpoint	3.400	+20	707 499 991	-3.5	0.000 000	-0.005



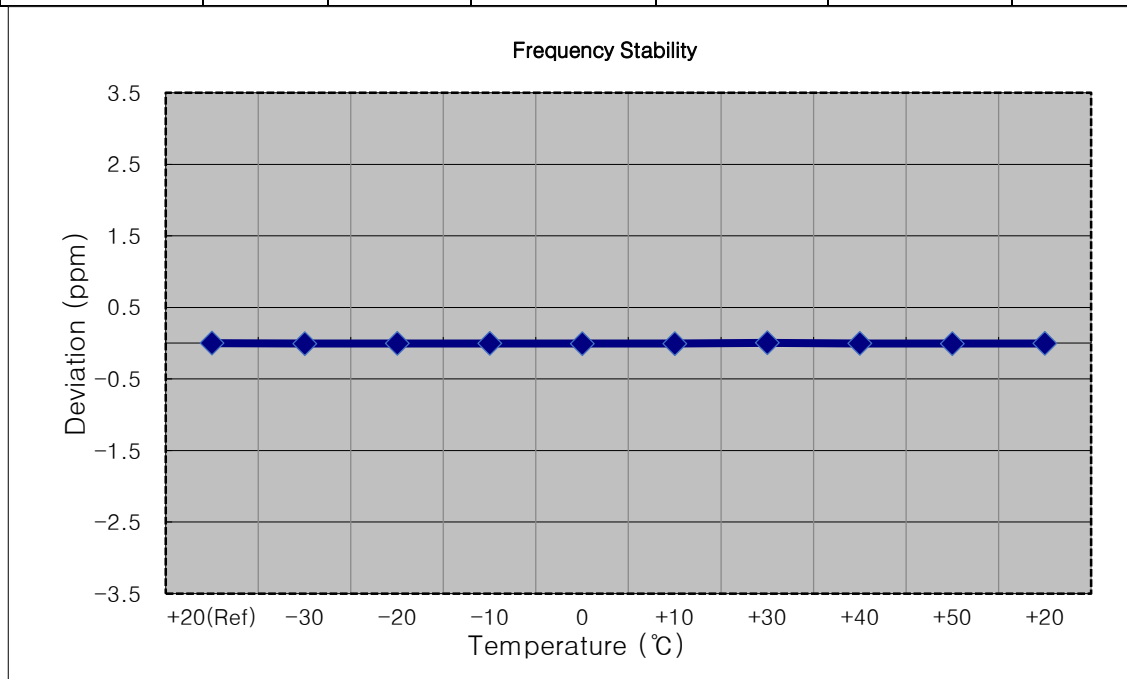
- ▣ MODE: LTE B12/17
- ▣ OPERATING FREQUENCY: 707,500,000 Hz
- ▣ CHANNEL: 23095 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.85 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	707 499 995	0.0	0.000 000	0.000
100%		-30	707 499 991	-3.7	-0.000 001	-0.005
100%		-20	707 499 999	4.1	0.000 001	0.006
100%		-10	707 499 997	1.7	0.000 000	0.002
100%		0	707 499 993	-2.1	0.000 000	-0.003
100%		+10	707 499 989	-6.2	-0.000 001	-0.009
100%		+30	707 499 997	2.5	0.000 000	0.004
100%		+40	707 499 992	-2.8	0.000 000	-0.004
100%		+50	707 499 990	-5.3	-0.000 001	-0.007
Batt. Endpoint	3.400	+20	707 499 988	-7.2	-0.000 001	-0.010



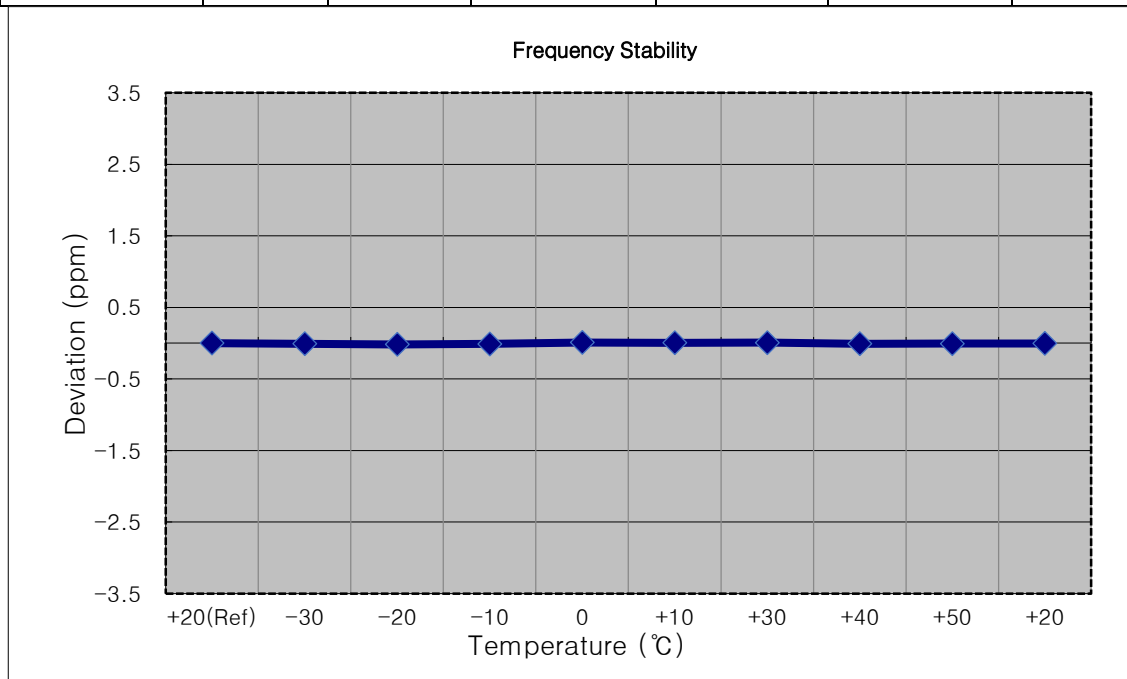
- ▣ MODE: LTE B12/17
- ▣ OPERATING FREQUENCY: 707,500,000 Hz
- ▣ CHANNEL: 23095 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.85 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	707 499 994	0.0	0.000 000	0.000
100%		-30	707 499 990	-4.0	-0.000 001	-0.006
100%		-20	707 499 991	-3.1	0.000 000	-0.004
100%		-10	707 499 991	-3.1	0.000 000	-0.004
100%		0	707 499 990	-4.6	-0.000 001	-0.007
100%		+10	707 499 990	-4.6	-0.000 001	-0.007
100%		+30	707 499 998	3.5	0.000 000	0.005
100%		+40	707 499 991	-3.5	0.000 000	-0.005
100%		+50	707 499 989	-4.8	-0.000 001	-0.007
Batt. Endpoint	3.400	+20	707 499 991	-2.9	0.000 000	-0.004



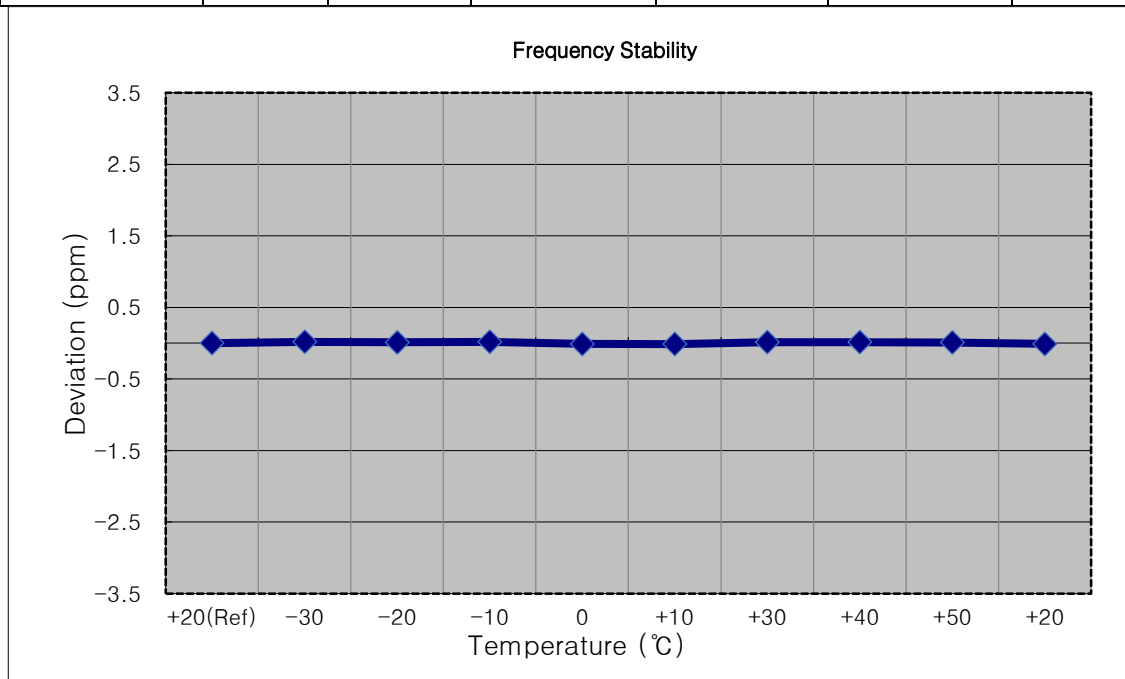
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 715,300,000 Hz
- ▣ CHANNEL: 23173 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 3.85 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	715 299 993	0.0	0.000 000	0.000
100%		-30	715 299 986	-6.8	-0.000 001	-0.010
100%		-20	715 299 980	-13.2	-0.000 002	-0.018
100%		-10	715 299 986	-7.0	-0.000 001	-0.010
100%		0	715 300 000	6.9	0.000 001	0.010
100%		+10	715 299 997	3.9	0.000 001	0.005
100%		+30	715 299 998	4.4	0.000 001	0.006
100%		+40	715 299 988	-5.6	-0.000 001	-0.008
100%		+50	715 299 988	-4.9	-0.000 001	-0.007
Batt. Endpoint	3.400	+20	715 299 990	-3.6	-0.000 001	-0.005



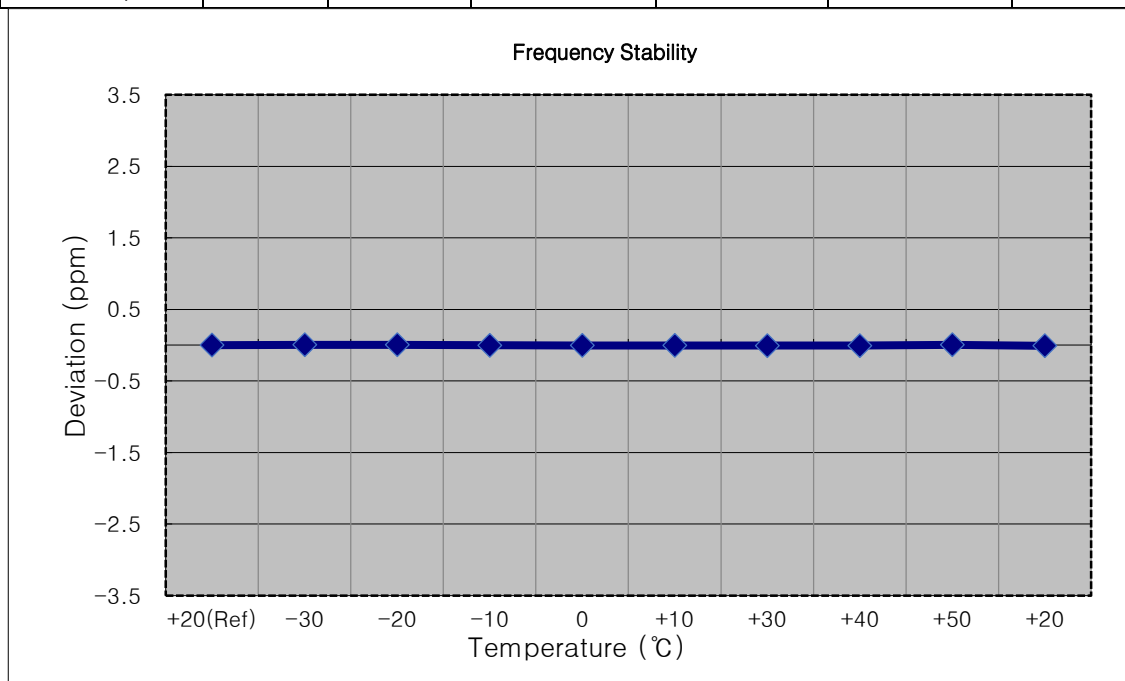
- ▣ MODE: LTE B12
- ▣ OPERATING FREQUENCY: 714,500,000 Hz
- ▣ CHANNEL: 23165 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.85 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	714 500 017	0.0	0.000 000	0.000
100%		-30	714 500 030	13.3	0.000 002	0.019
100%		-20	714 500 025	7.9	0.000 001	0.011
100%		-10	714 500 030	13.3	0.000 002	0.019
100%		0	714 500 010	-7.1	-0.000 001	-0.010
100%		+10	714 500 007	-9.3	-0.000 001	-0.013
100%		+30	714 500 026	9.2	0.000 001	0.013
100%		+40	714 500 026	9.7	0.000 001	0.014
100%		+50	714 500 023	6.6	0.000 001	0.009
Batt. Endpoint	3.400	+20	714 500 010	-7.1	-0.000 001	-0.010



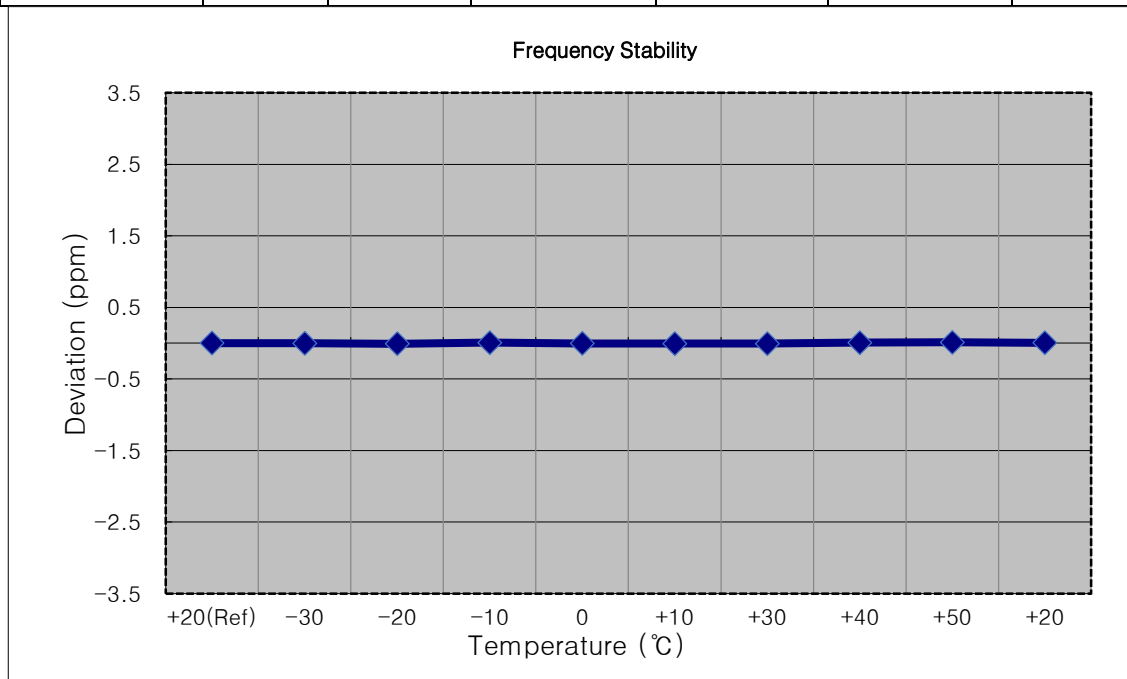
- ▣ MODE: LTE B12/17
- ▣ OPERATING FREQUENCY: 713,500,000 Hz
- ▣ CHANNEL: 23155 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.85 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	713 499 992	0.0	0.000 000	0.000
100%		-30	713 499 994	2.7	0.000 000	0.004
100%		-20	713 499 996	4.1	0.000 001	0.006
100%		-10	713 499 990	-1.4	0.000 000	-0.002
100%		0	713 499 989	-2.5	0.000 000	-0.004
100%		+10	713 499 989	-2.7	0.000 000	-0.004
100%		+30	713 499 987	-4.3	-0.000 001	-0.006
100%		+40	713 499 986	-5.3	-0.000 001	-0.007
100%		+50	713 499 996	4.0	0.000 001	0.006
Batt. Endpoint	3.400	+20	713 499 985	-6.6	-0.000 001	-0.009



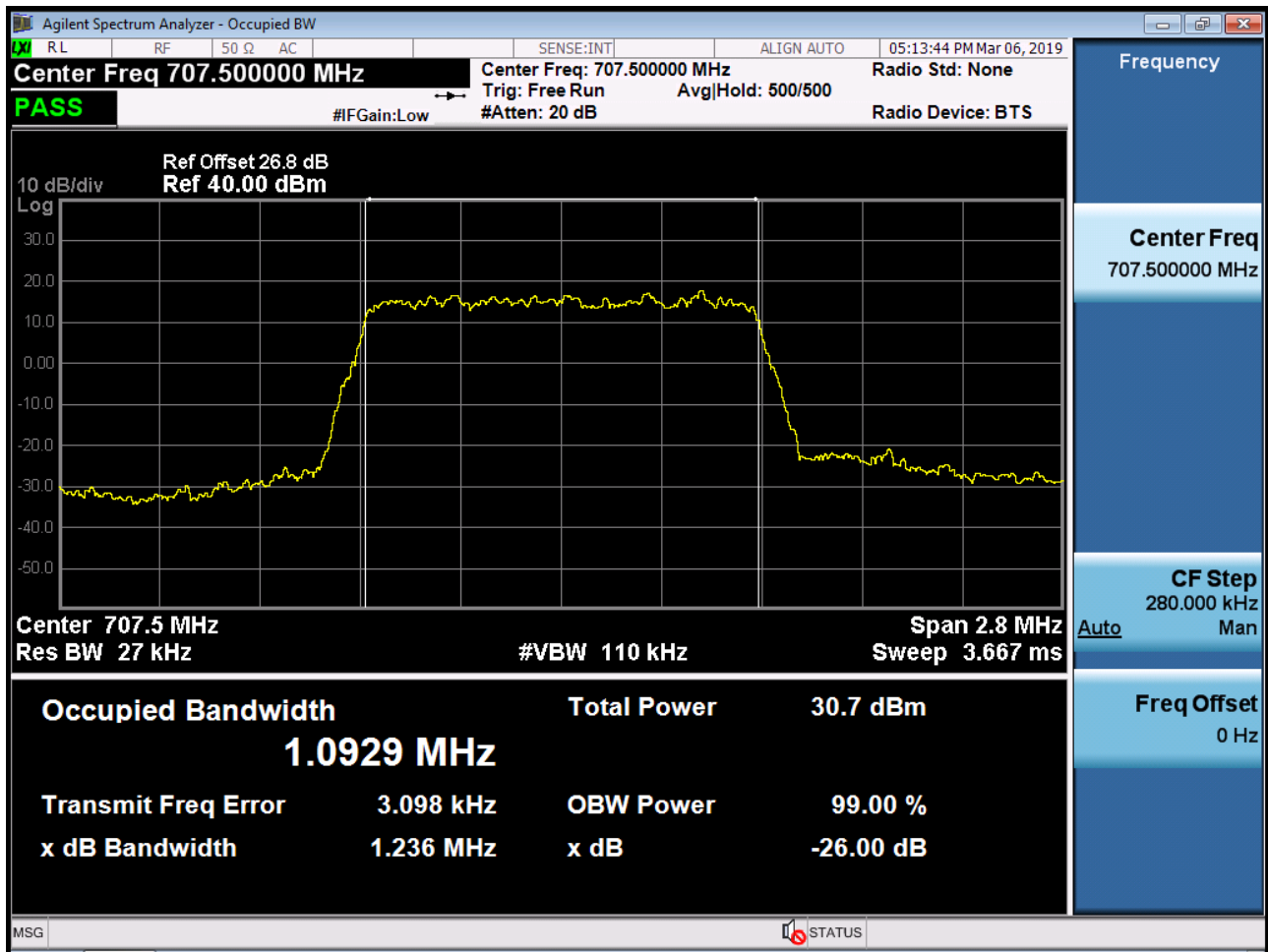
- ▣ MODE: LTE B12/17
- ▣ OPERATING FREQUENCY: 711,000,000 Hz
- ▣ CHANNEL: 23130 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.85 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.850	+20(Ref)	711 000 003	0.0	0.000 000	0.000
100%		-30	711 000 002	-1.8	0.000 000	-0.003
100%		-20	710 999 998	-5.5	-0.000 001	-0.008
100%		-10	711 000 008	4.3	0.000 001	0.006
100%		0	711 000 001	-2.3	0.000 000	-0.003
100%		+10	710 999 999	-4.1	-0.000 001	-0.006
100%		+30	710 999 999	-4.6	-0.000 001	-0.006
100%		+40	711 000 009	5.2	0.000 001	0.007
100%		+50	711 000 012	8.7	0.000 001	0.012
Batt. Endpoint	3.400	+20	711 000 007	3.2	0.000 000	0.005

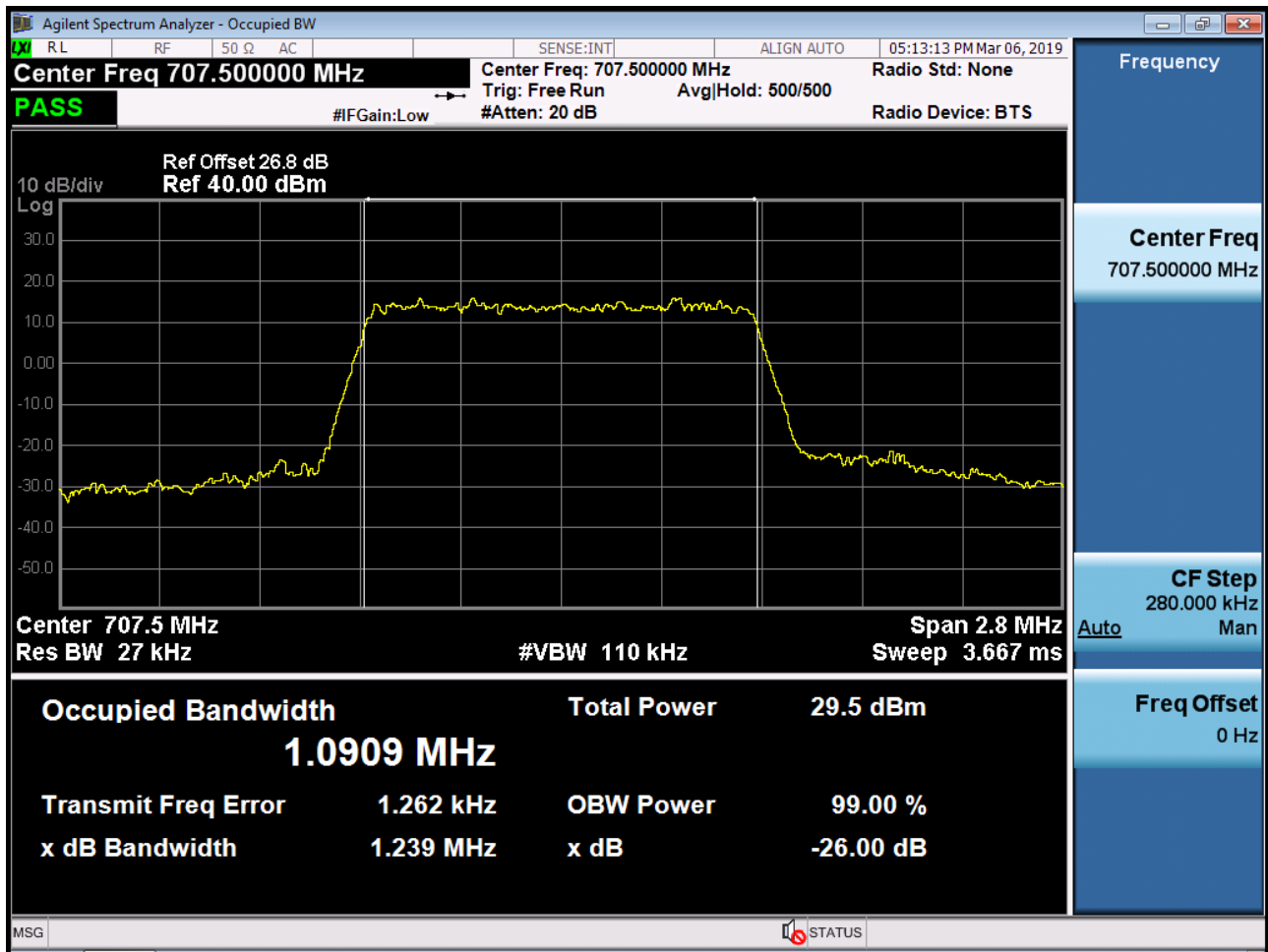


9. TEST PLOTS

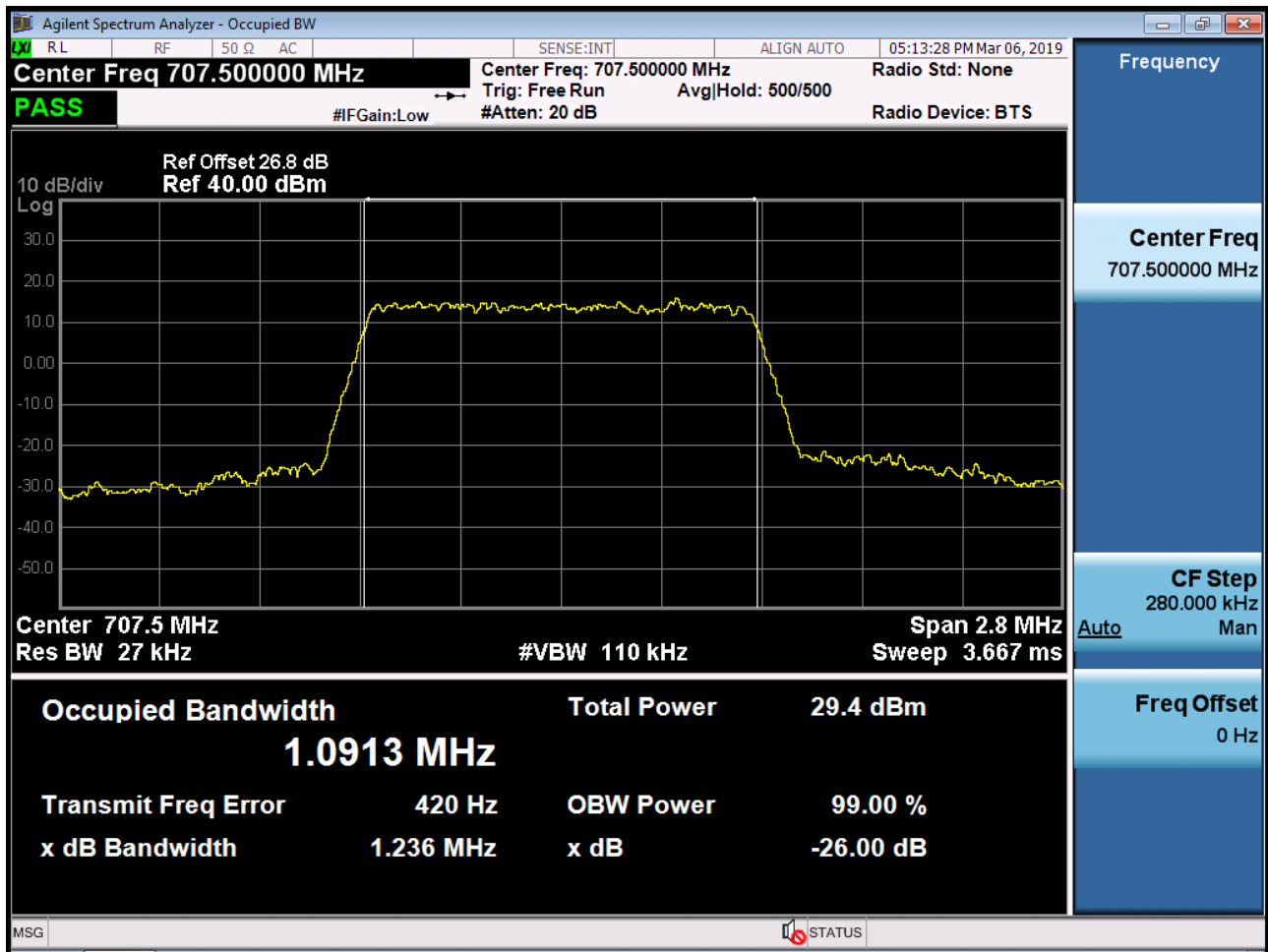
BAND 12. Occupied Bandwidth Plot (1.4M BW Ch.23095 QPSK_RB6_0)



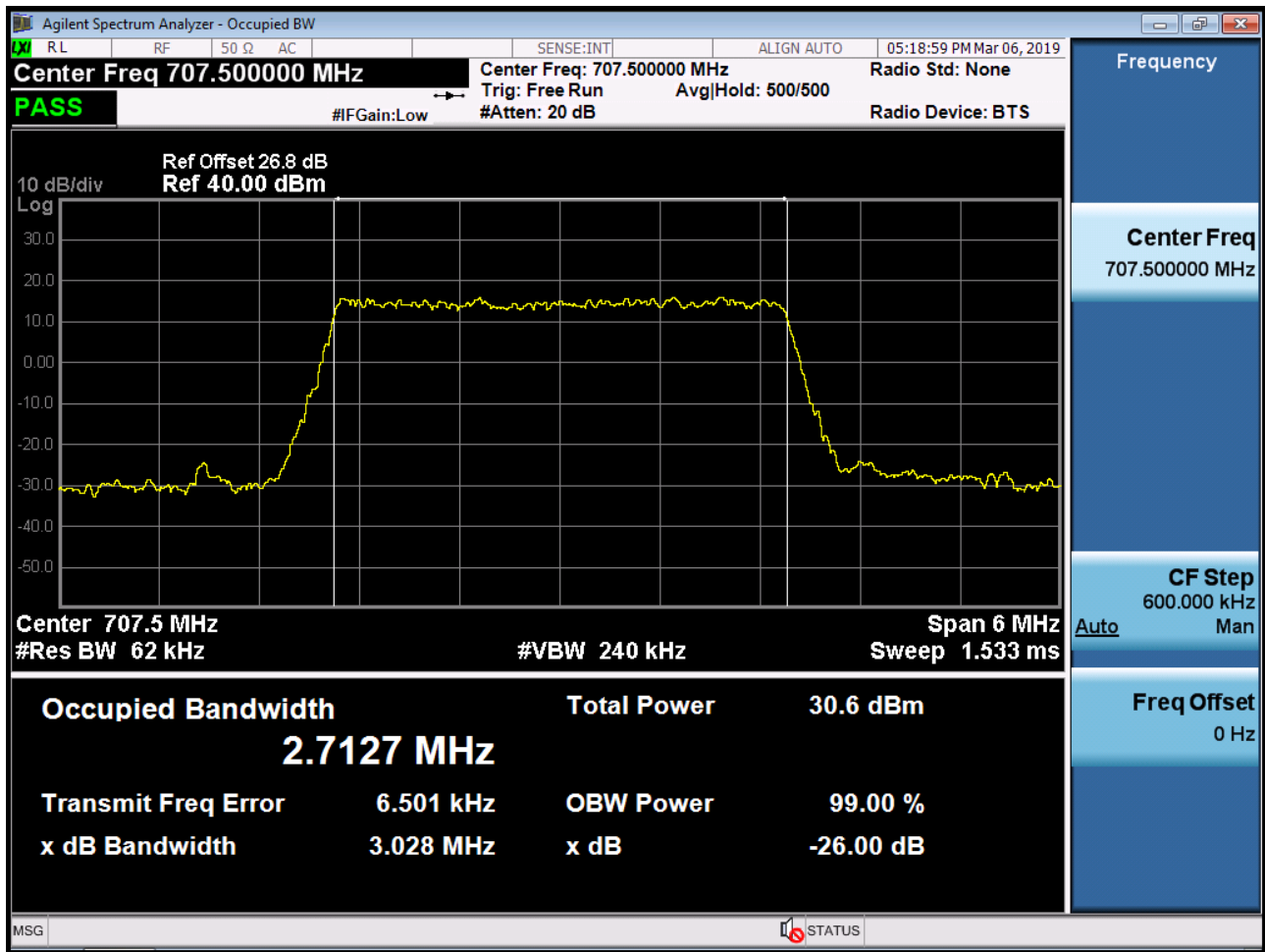
BAND 12. Occupied Bandwidth Plot (1.4M BW Ch.23095 16QAM_RB6_0)



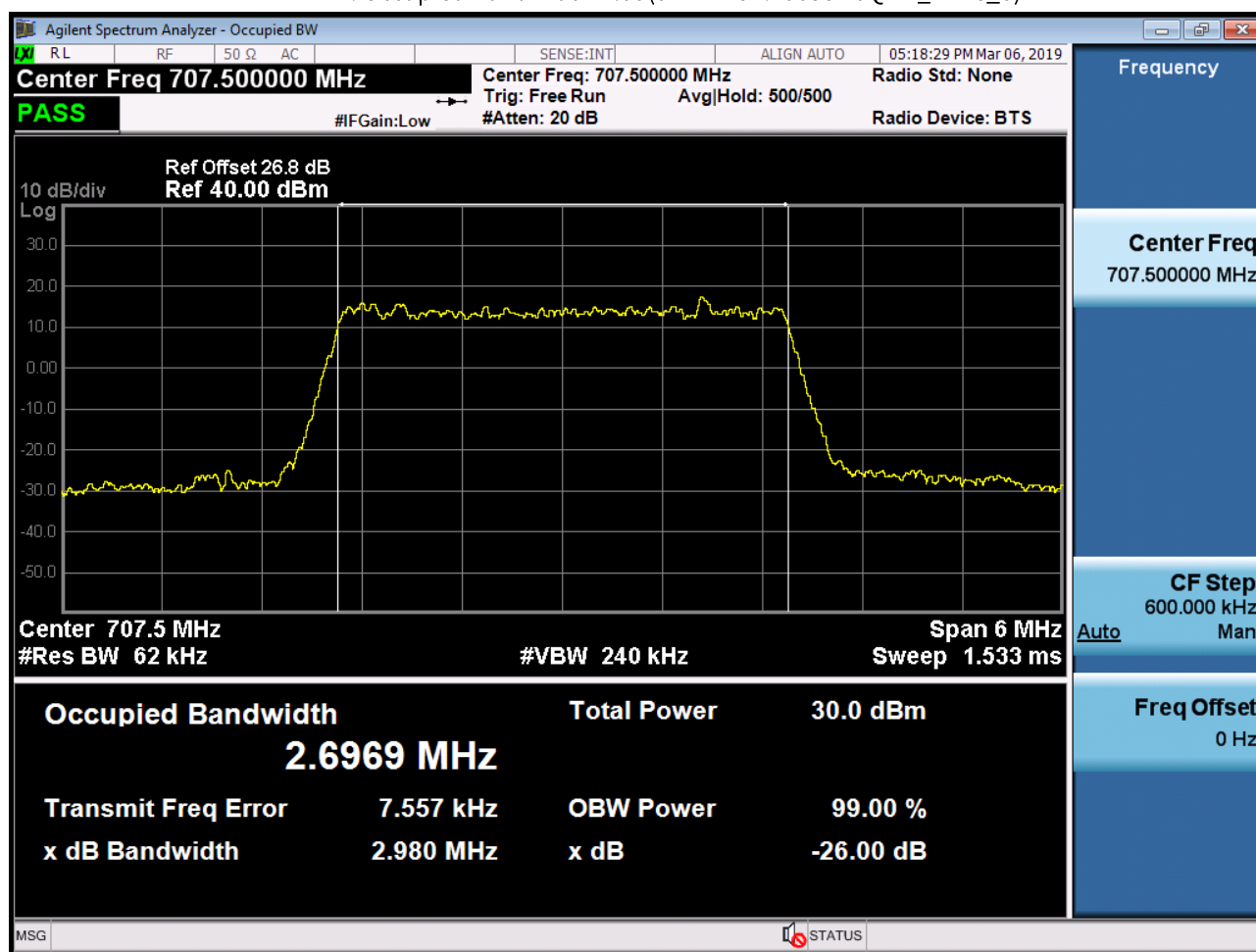
BAND 12. Occupied Bandwidth Plot (1.4M BW Ch.23095 64QAM_RB6_0)



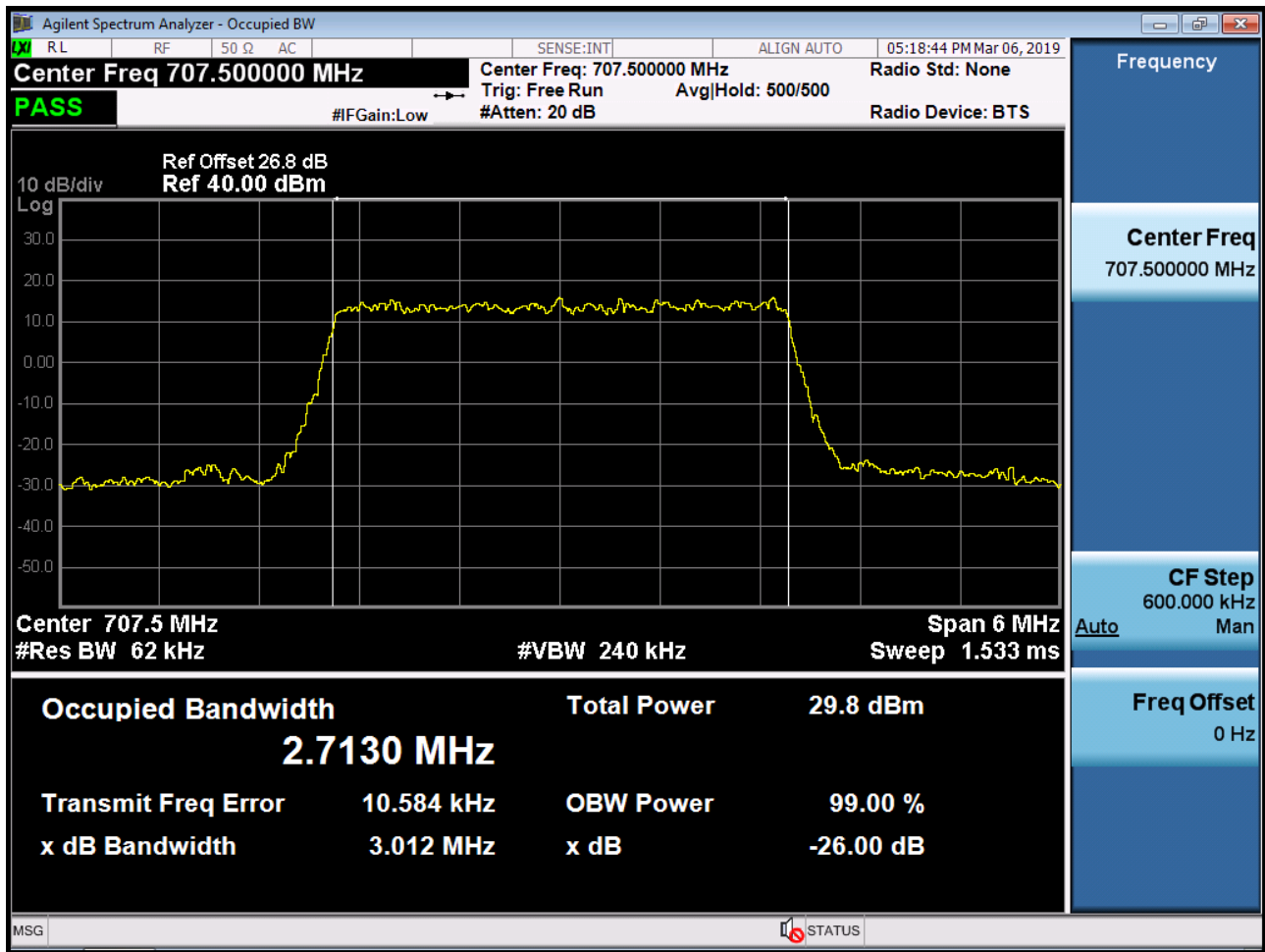
BAND 12. Occupied Bandwidth Plot (3M BW Ch.23095 QPSK_RB15_0)



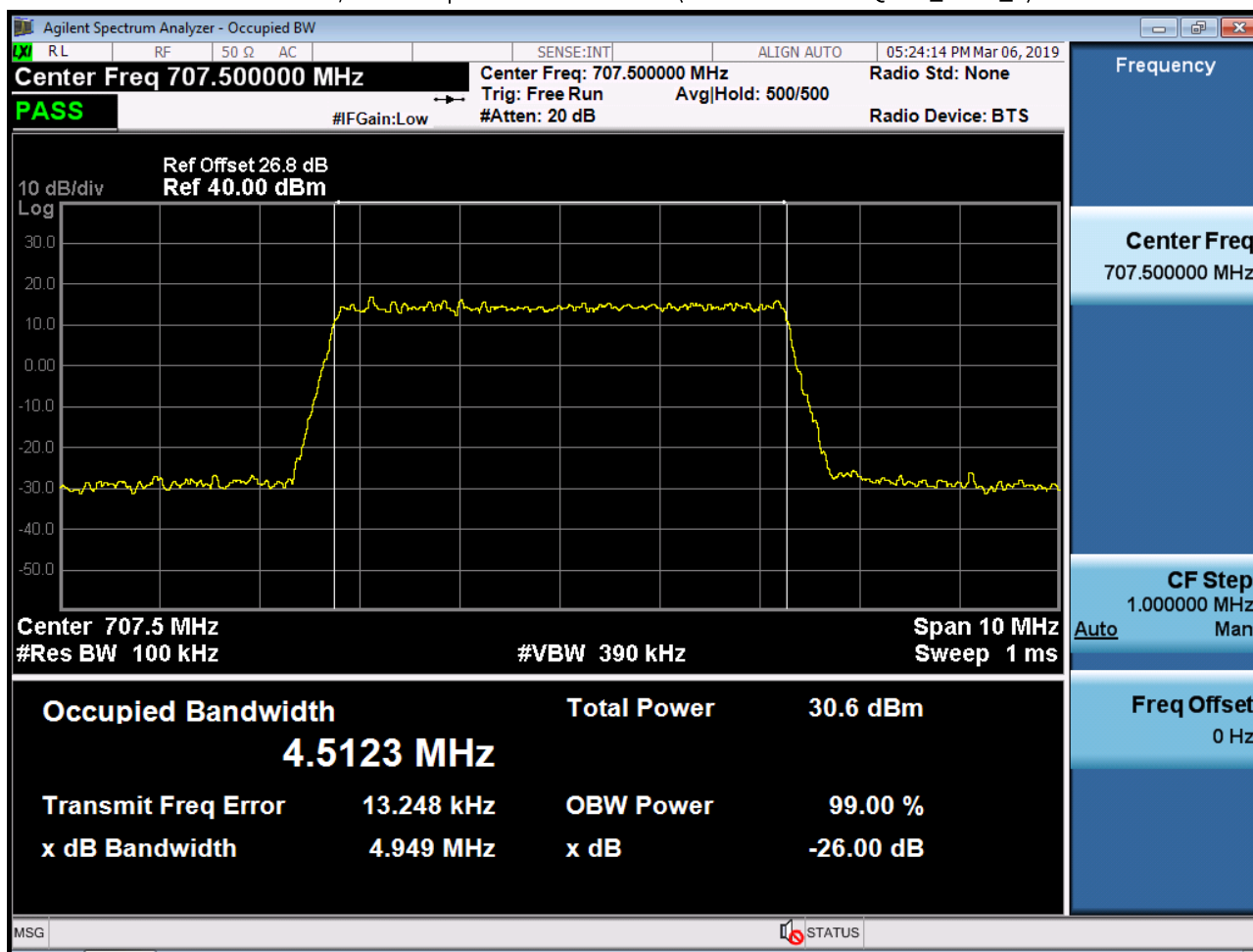
BAND 12. Occupied Bandwidth Plot (3M BW Ch.23095 16QAM_RB15_0)



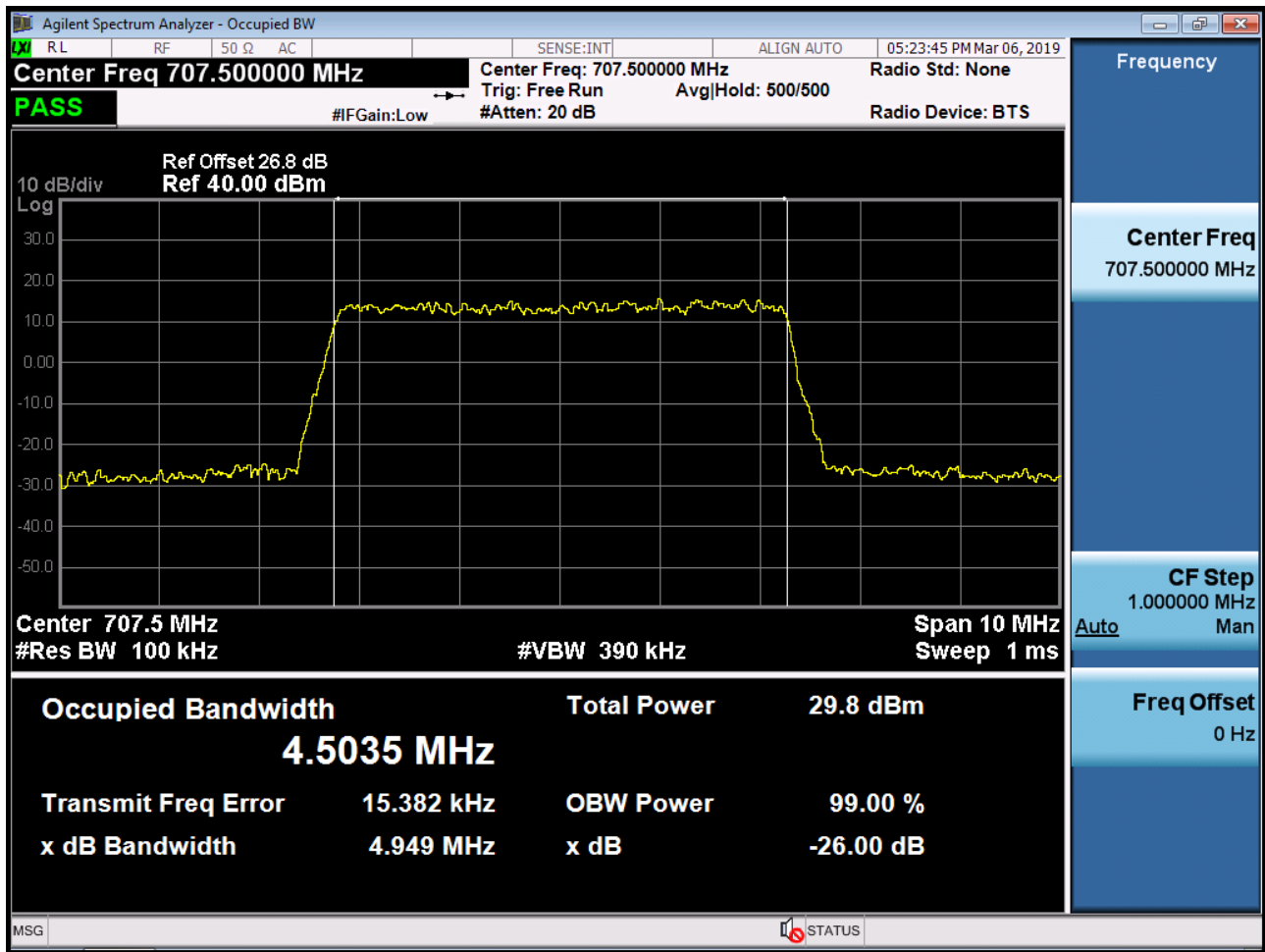
BAND 12. Occupied Bandwidth Plot (3M BW Ch.23095 64QAM_RB15_0)



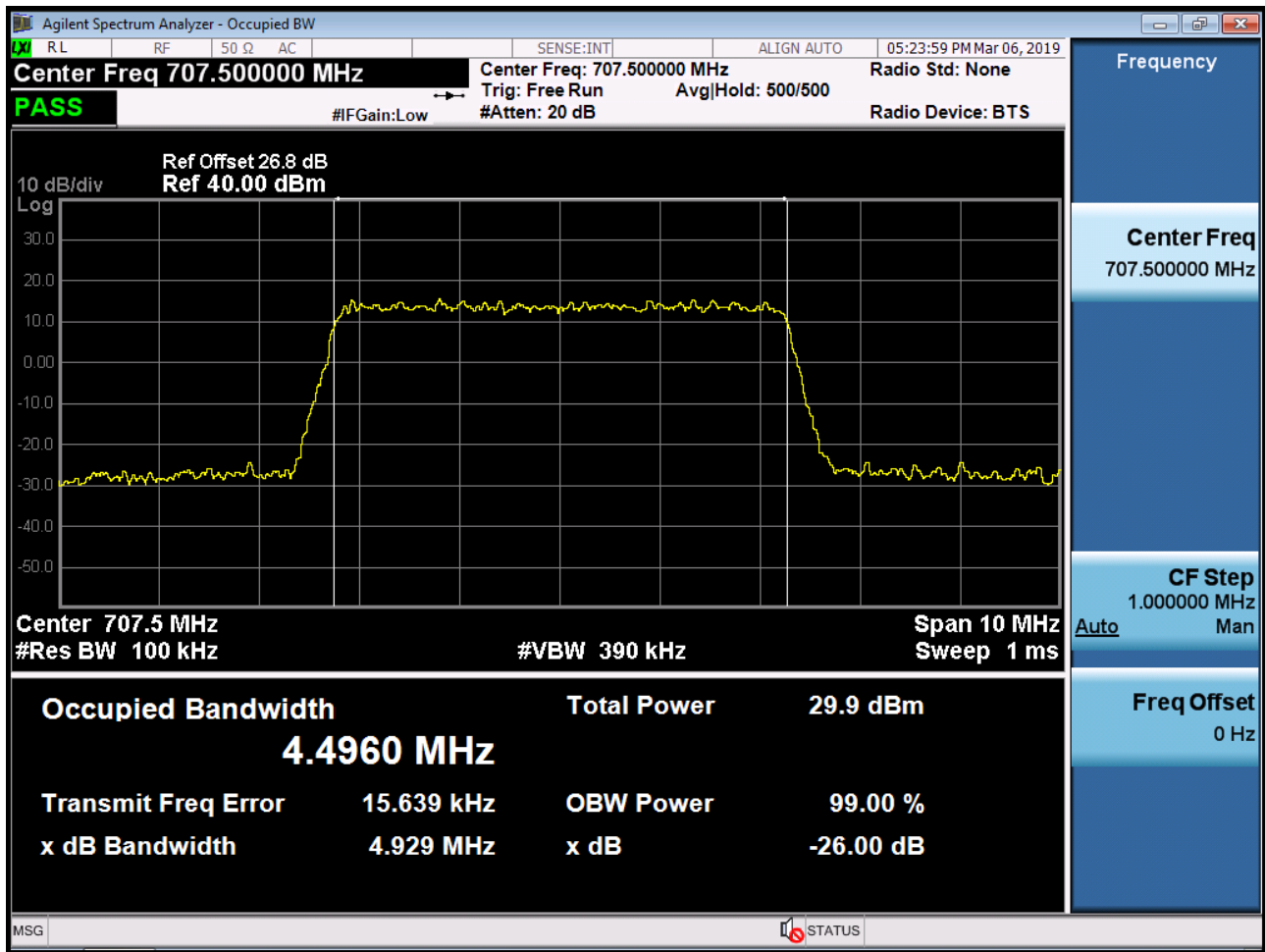
BAND 12 / 17. Occupied Bandwidth Plot (5M BW Ch.23095 QPSK_RB25_0)



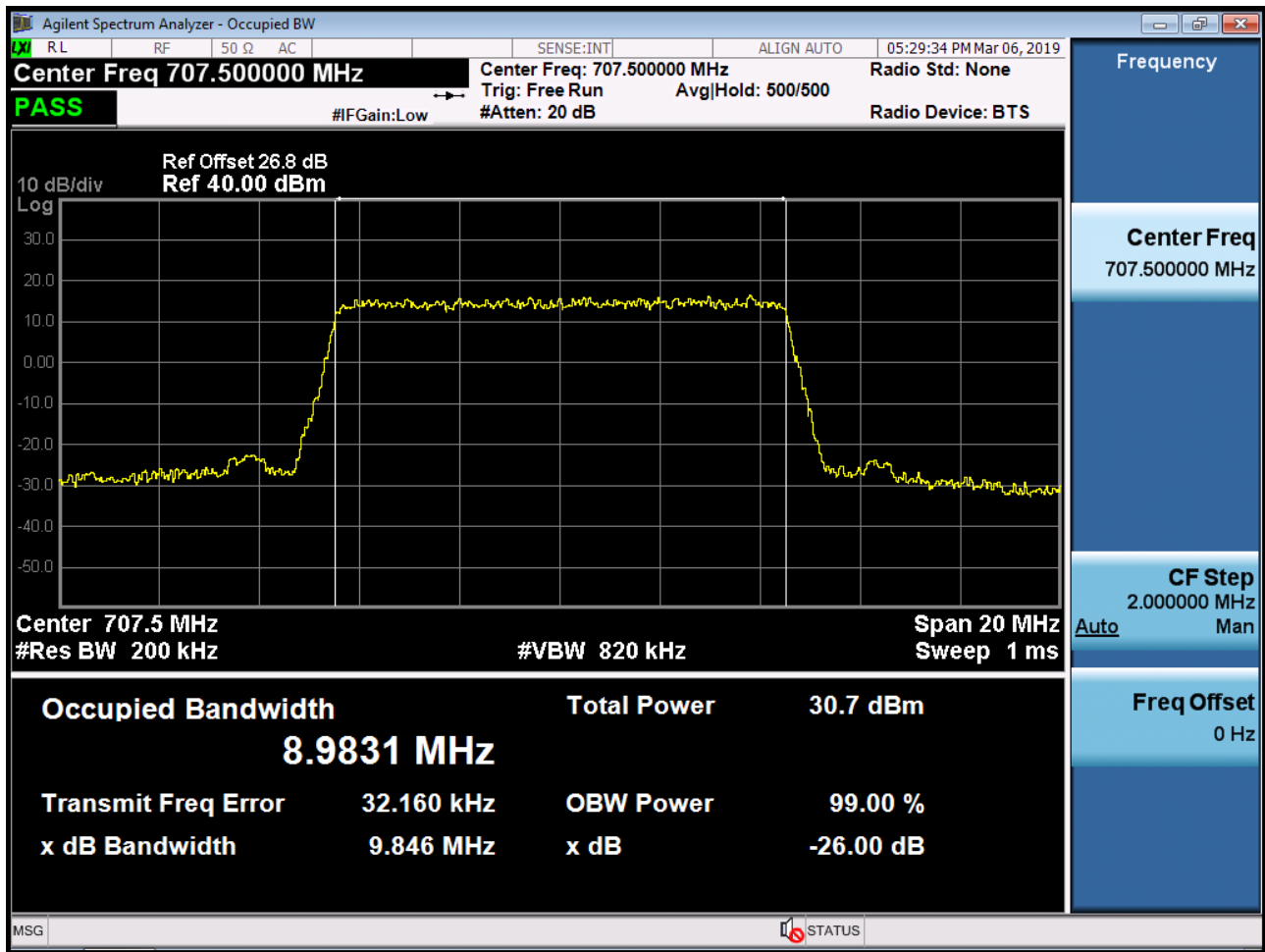
BAND 12 / 17. Occupied Bandwidth Plot (5M BW Ch.23095 16QAM_RB25_0)



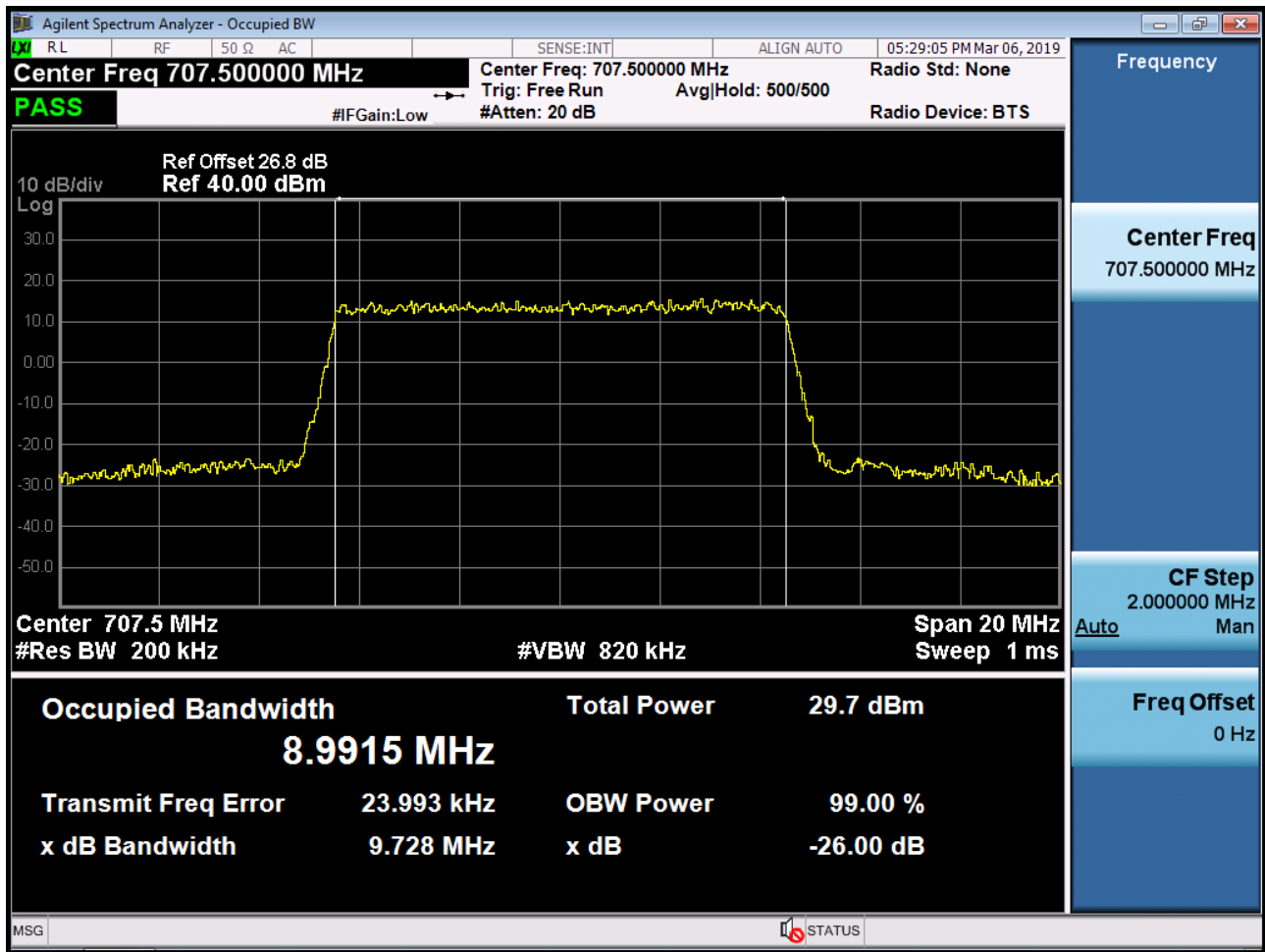
BAND 12 / 17. Occupied Bandwidth Plot (5M BW Ch.23095 64QAM_RB25_0)



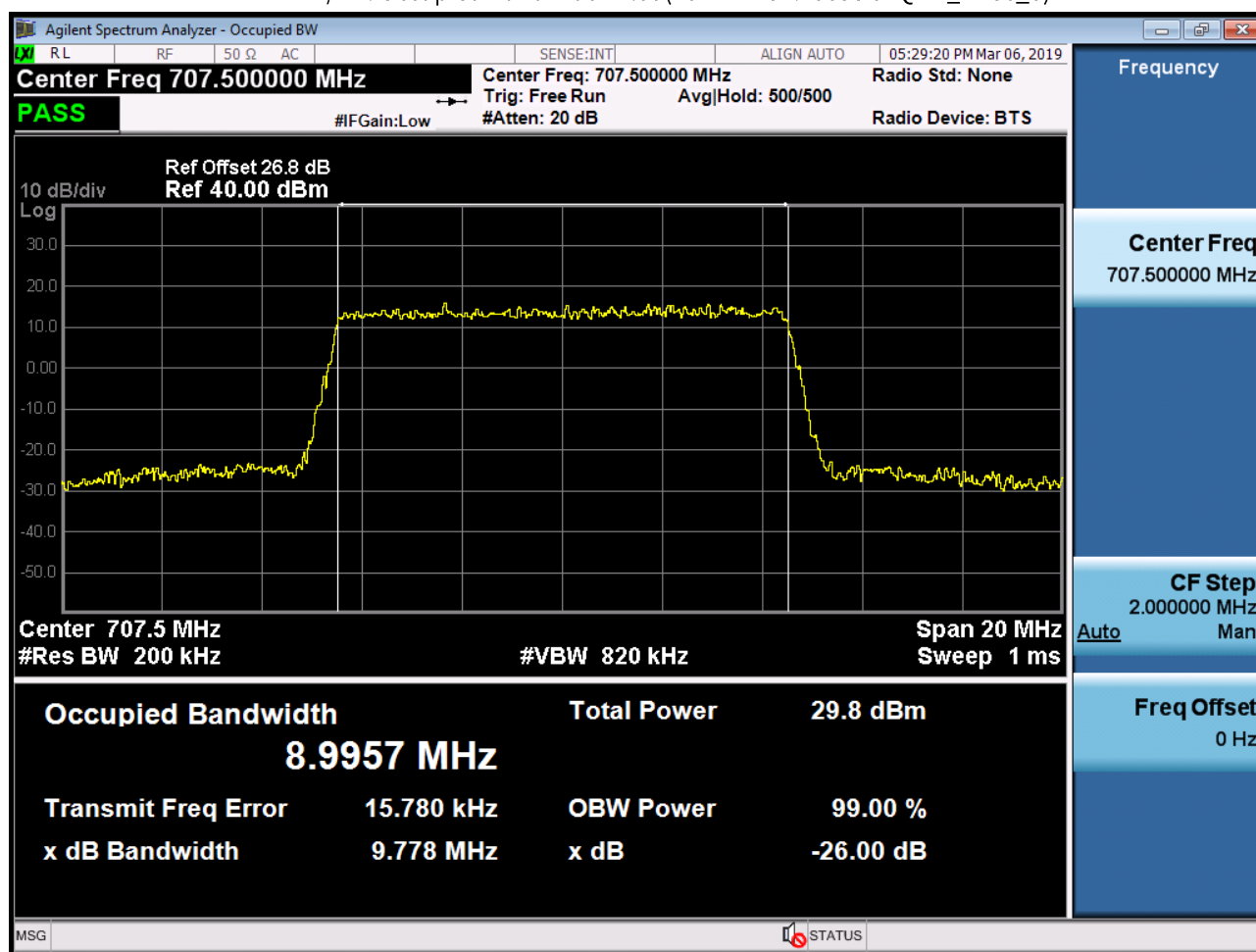
BAND 12 / 17. Occupied Bandwidth Plot (10M BW Ch.23095 QPSK_RB50_0)



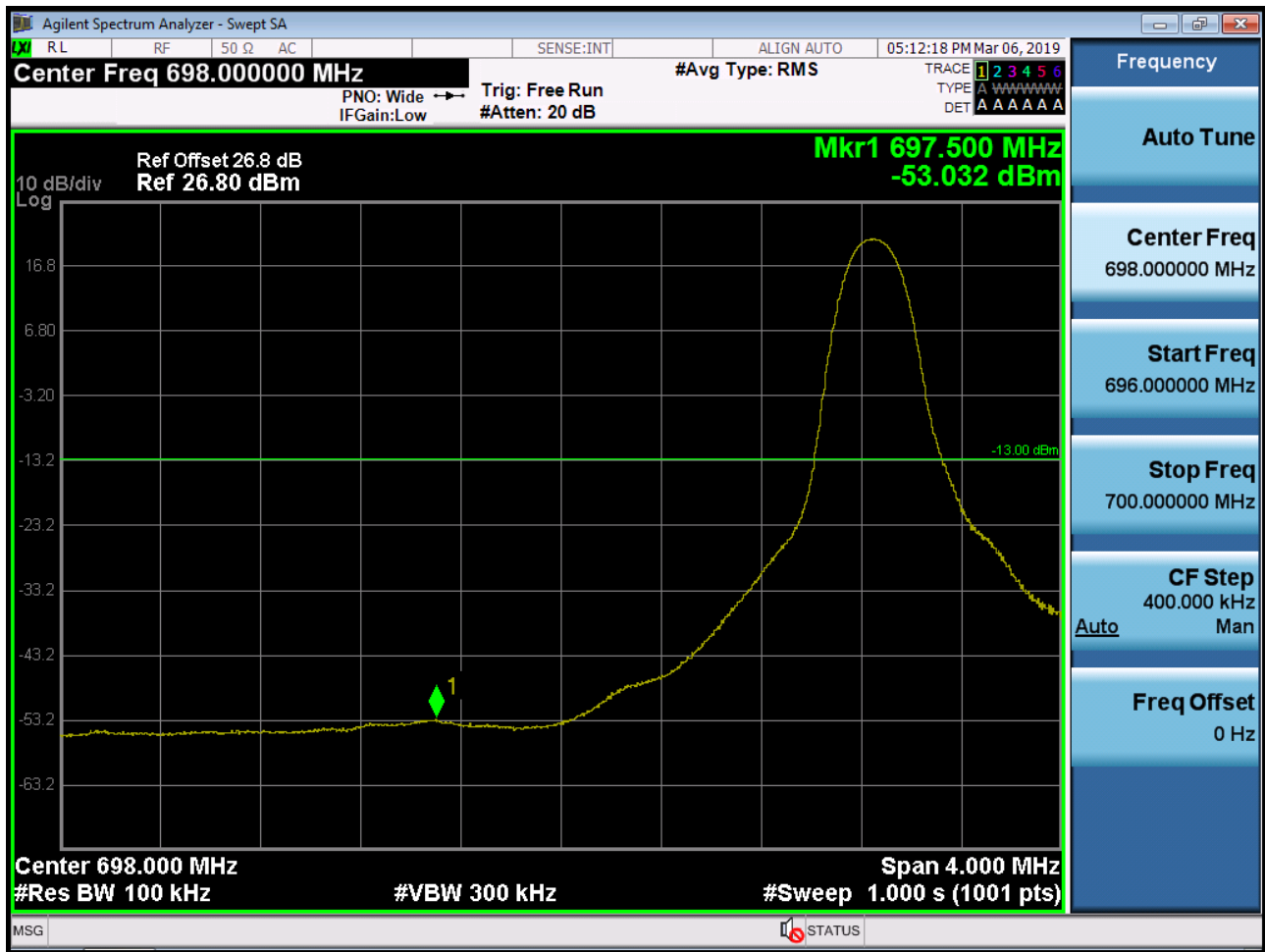
BAND 12 / 17. Occupied Bandwidth Plot (10M BW Ch.23095 16QAM_RB50_0)



BAND 12 / 17. Occupied Bandwidth Plot (10M BW Ch.23095 64QAM_RB50_0)



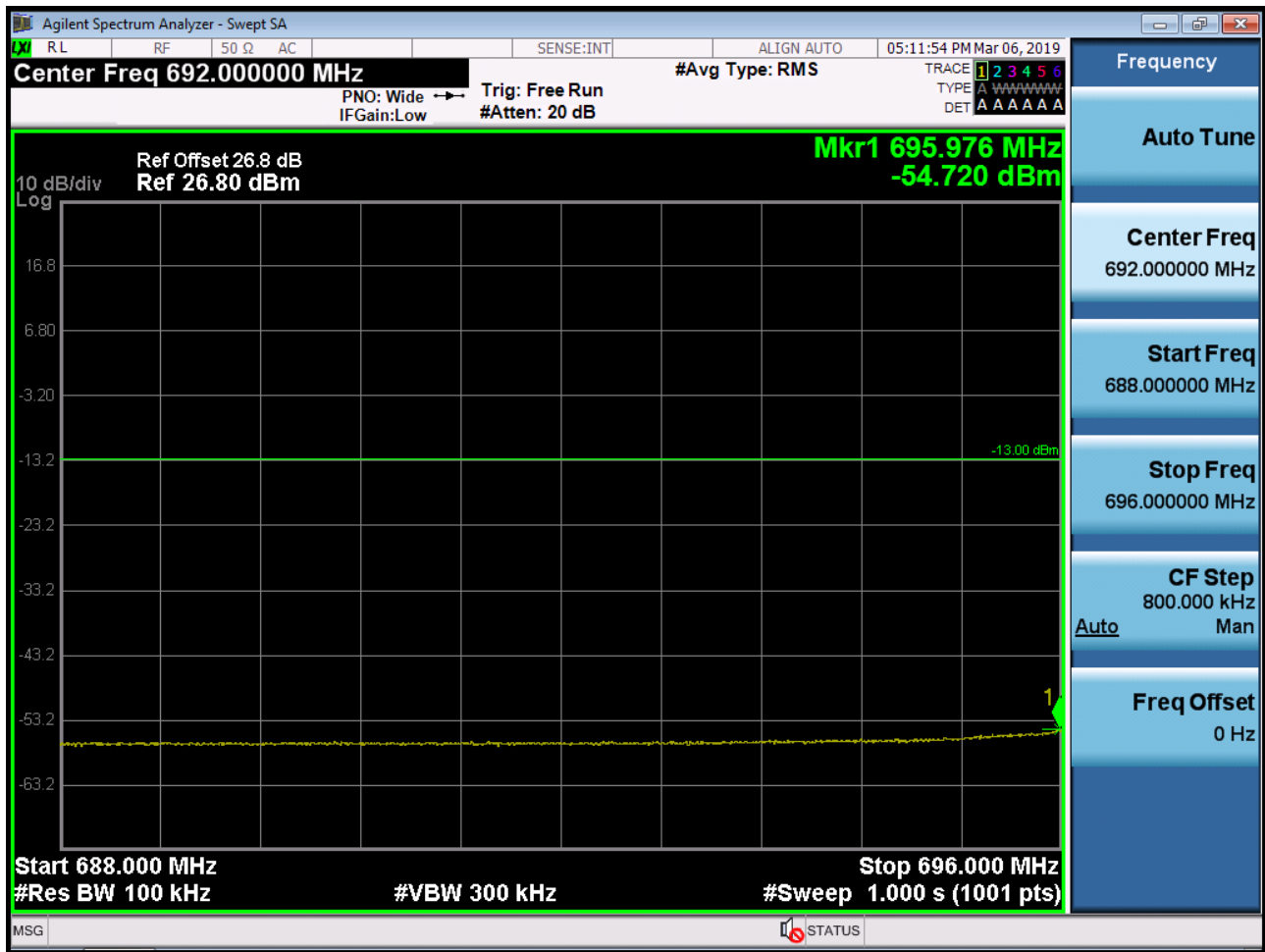
BAND 12. Lower Band Edge Plot (1.4M BW Ch.23017 QPSK_RB1_Offset 0)



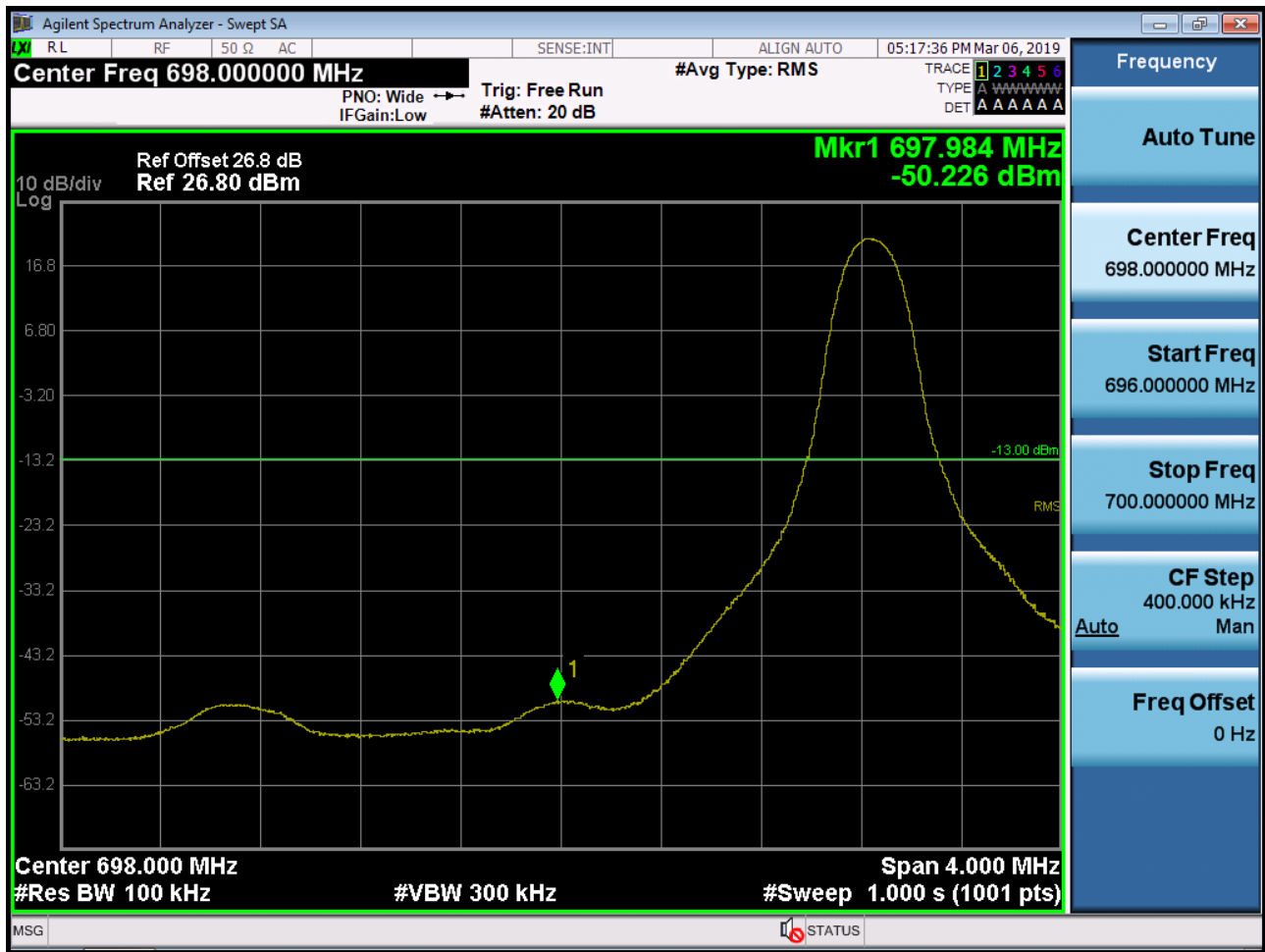
BAND 12. Lower Band Edge Plot (1.4M BW Ch.23017 QPSK_RB6_Offset 0)



BAND 12. Lower Extended Band Edge Plot (1.4M BW Ch.23017 QPSK_RB6_0)



BAND 12. Lower Band Edge Plot (3M BW Ch.23025 QPSK_RB1_Offset 0)



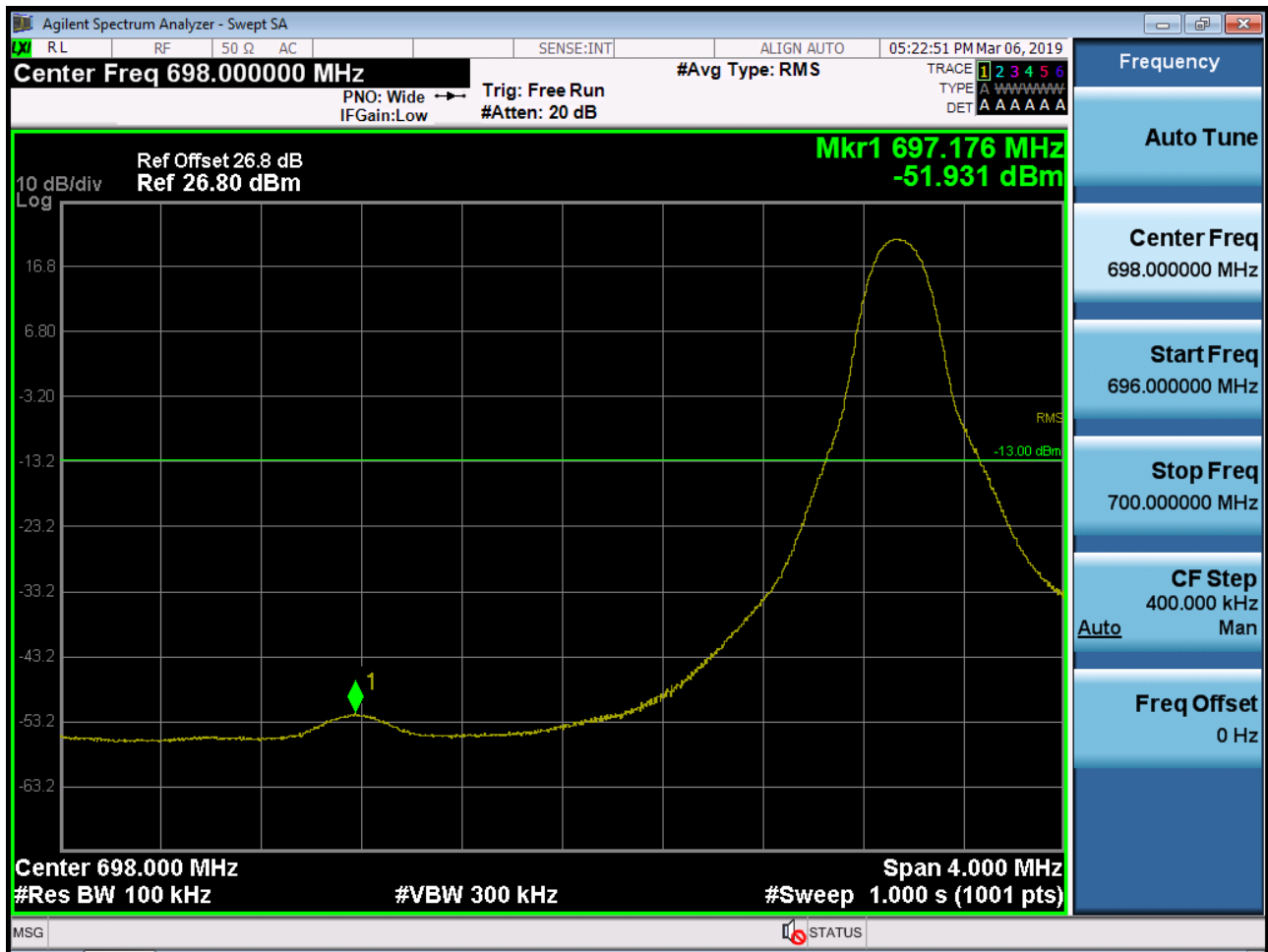
BAND 12. Lower Band Edge Plot (3M BW Ch.23025 QPSK_RB15_Offset 0)



BAND 12. Lower Extended Band Edge Plot (3M BW Ch.23025 QPSK_RB15_0)



BAND 12 / 17. Lower Band Edge Plot (5M BW Ch.23035 QPSK_RB1_Offset 0)



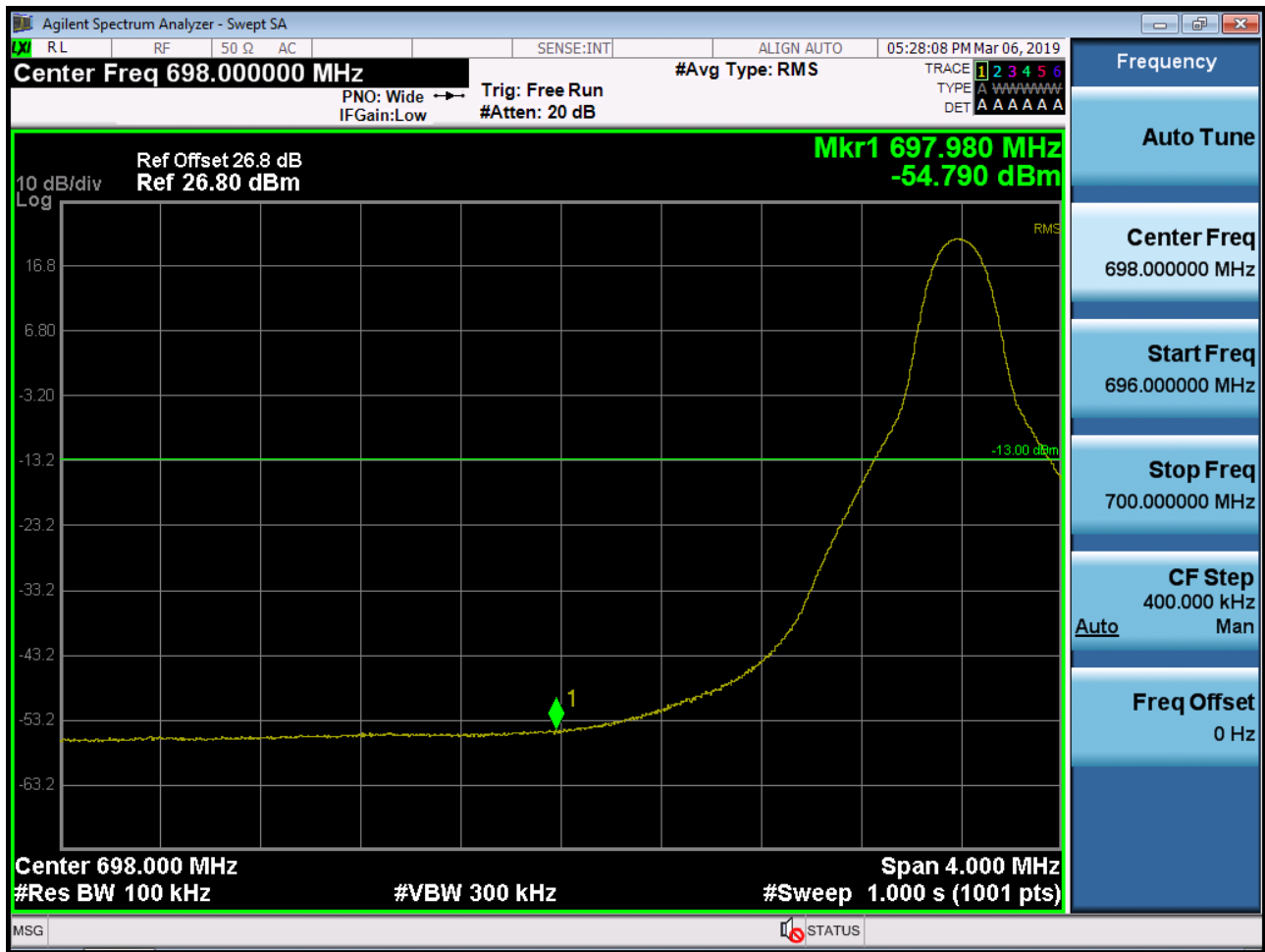
BAND 12 / 17. Lower Band Edge Plot (5M BW Ch.23035 QPSK_RB25_Offset 0)



BAND 12 / 17. Lower Extended Band Edge Plot (5M BW Ch.23035 QPSK_RB25_0)



BAND 12 / 17. Lower Band Edge Plot (10M BW Ch.23060 QPSK_RB1_Offset 0)



BAND 12 / 17. Lower Band Edge Plot (10M BW Ch.23060 QPSK_RB50_Offset 0)



BAND 12 / 17. Lower Extended Band Edge Plot (10M BW Ch.23060 QPSK_RB50_0)



BAND 12. Upper Band Edge Plot (1.4M BW Ch.23173 QPSK_RB1_Offset 5)



BAND 12. Upper Band Edge Plot (1.4M BW Ch.23173 QPSK_RB6_Offset 0)



BAND 12. Upper Extended Band Edge Plot (1.4M BW Ch.23173 QPSK_RB6_0)



BAND 12. Upper Band Edge Plot (3M BW Ch.23165 QPSK_RB1_Offset 14)-1



BAND 12. Upper Band Edge Plot (3M BW Ch.23165 QPSK_RB1_Offset 14)-2



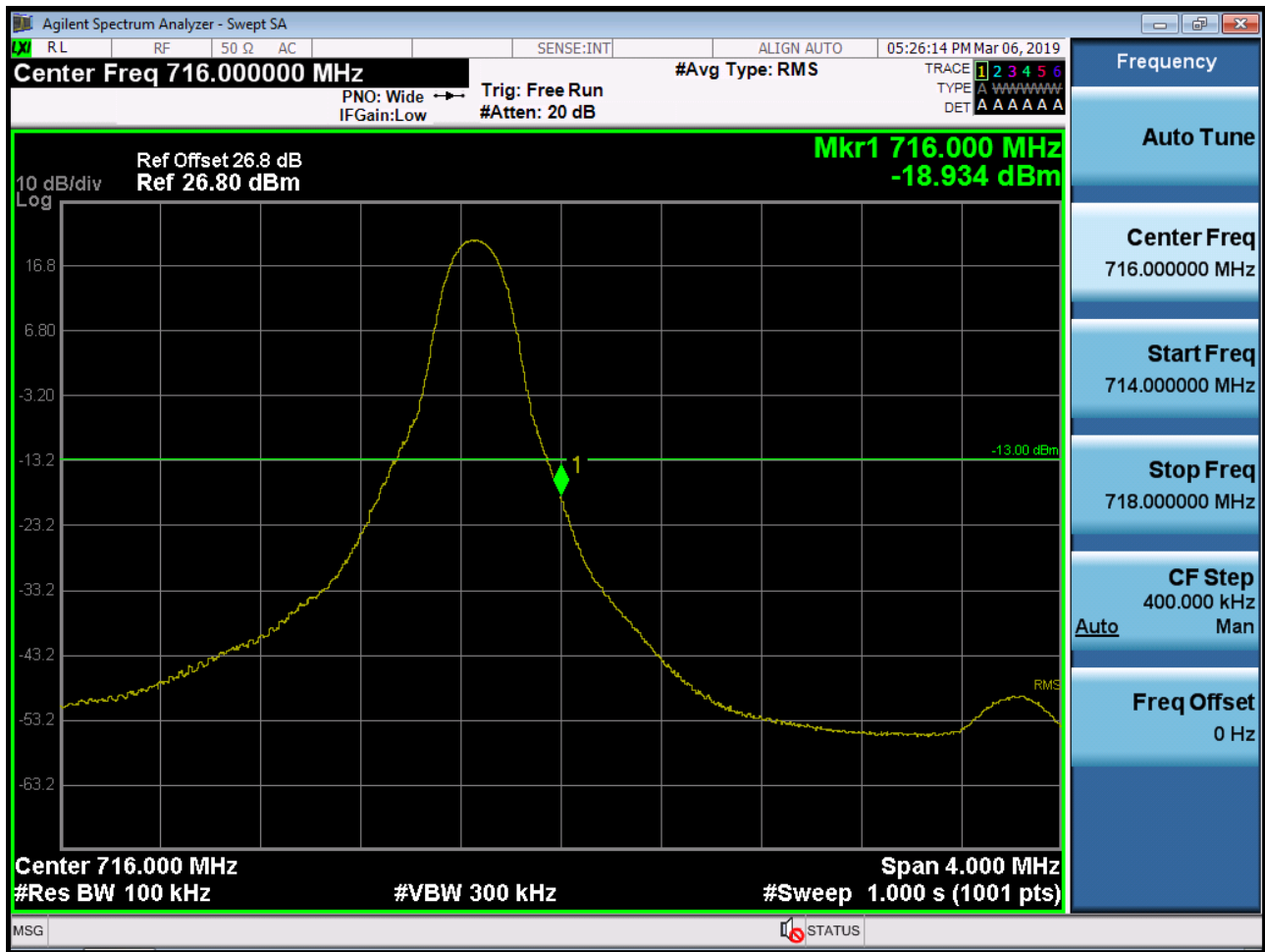
BAND 12. Upper Band Edge Plot (3M BW Ch.23165 QPSK_RB15_Offset 0)



BAND 12. Upper Extended Band Edge Plot (3M BW Ch.23165 QPSK_RB15_0)



BAND 12 / 17. Upper Band Edge Plot (5M BW Ch.23155 QPSK_RB1_Offset 24)



BAND 12 / 17. Upper Band Edge Plot (5M BW Ch.23155 QPSK_RB25_Offset 0)



BAND 12 / 17. Upper Extended Band Edge Plot (5M BW Ch.23155 QPSK_RB25_0)



BAND 12 / 17. Upper Band Edge Plot (10M BW Ch.23130 QPSK_RB1_Offset 49)



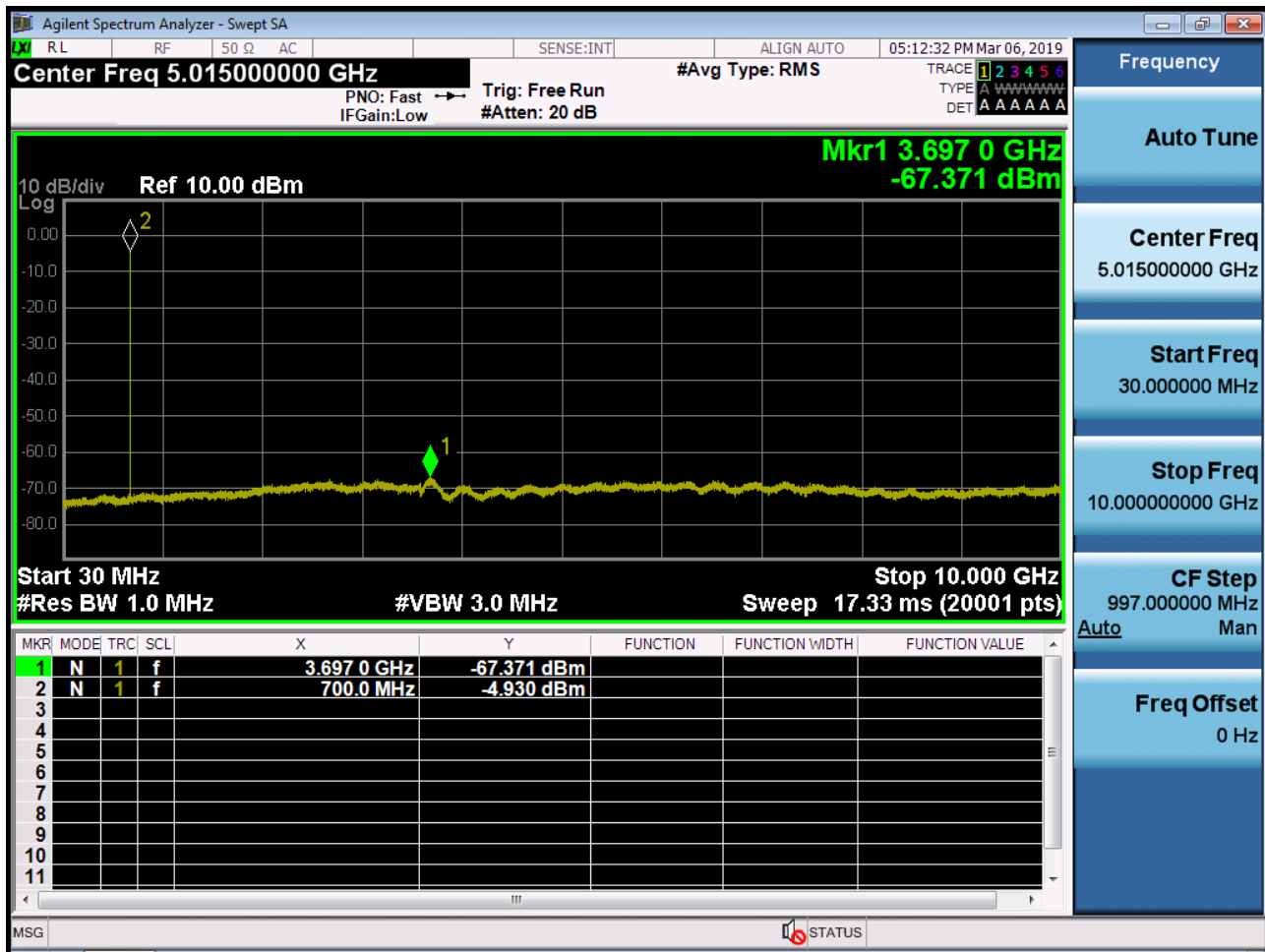
BAND 12 / 17. Upper Band Edge Plot (10M BW Ch.23130 QPSK_RB50_Offset 0)



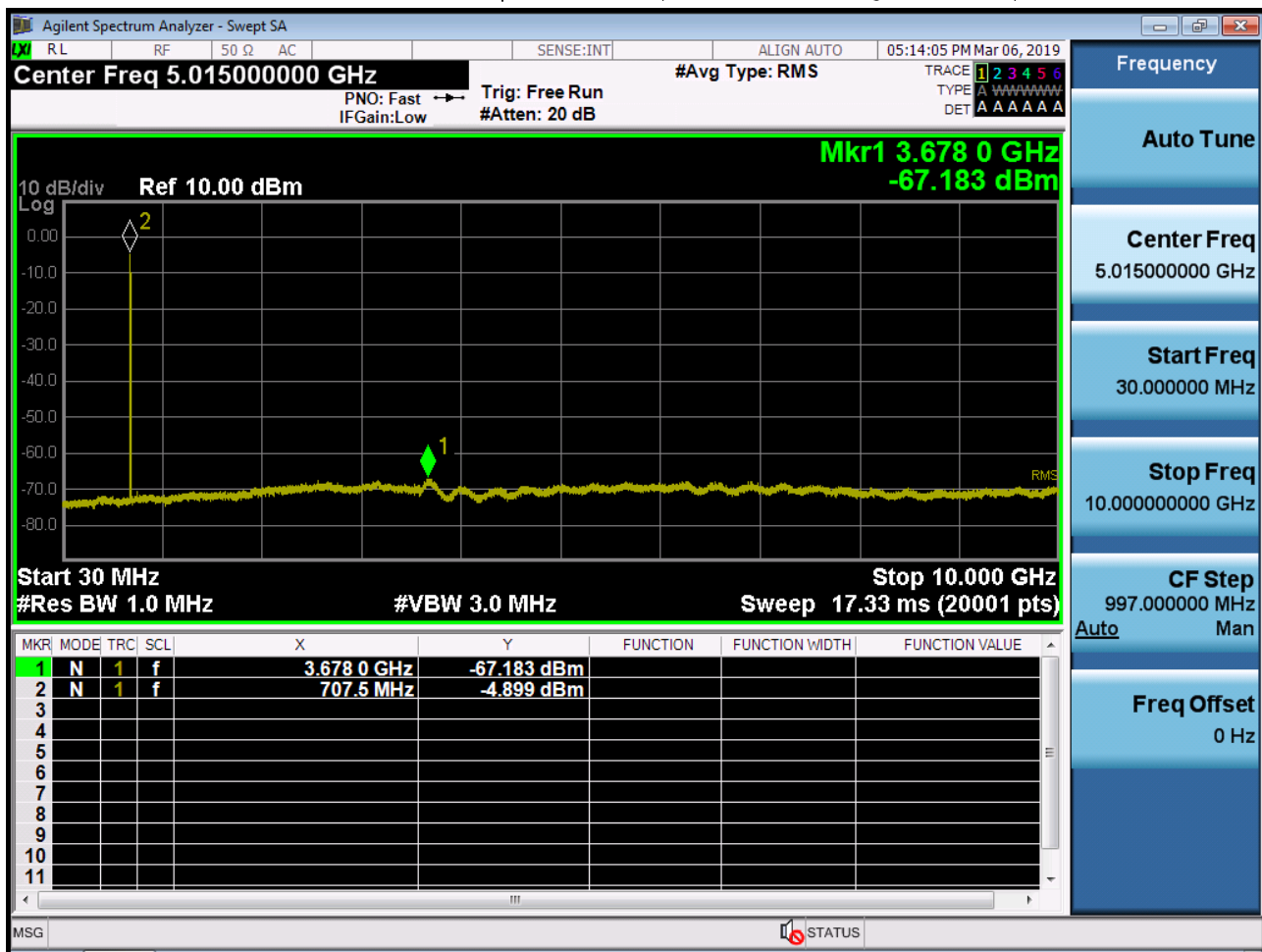
BAND 12 / 17. Upper Extended Band Edge Plot (10M BW Ch.23130 QPSK_RB50_0)



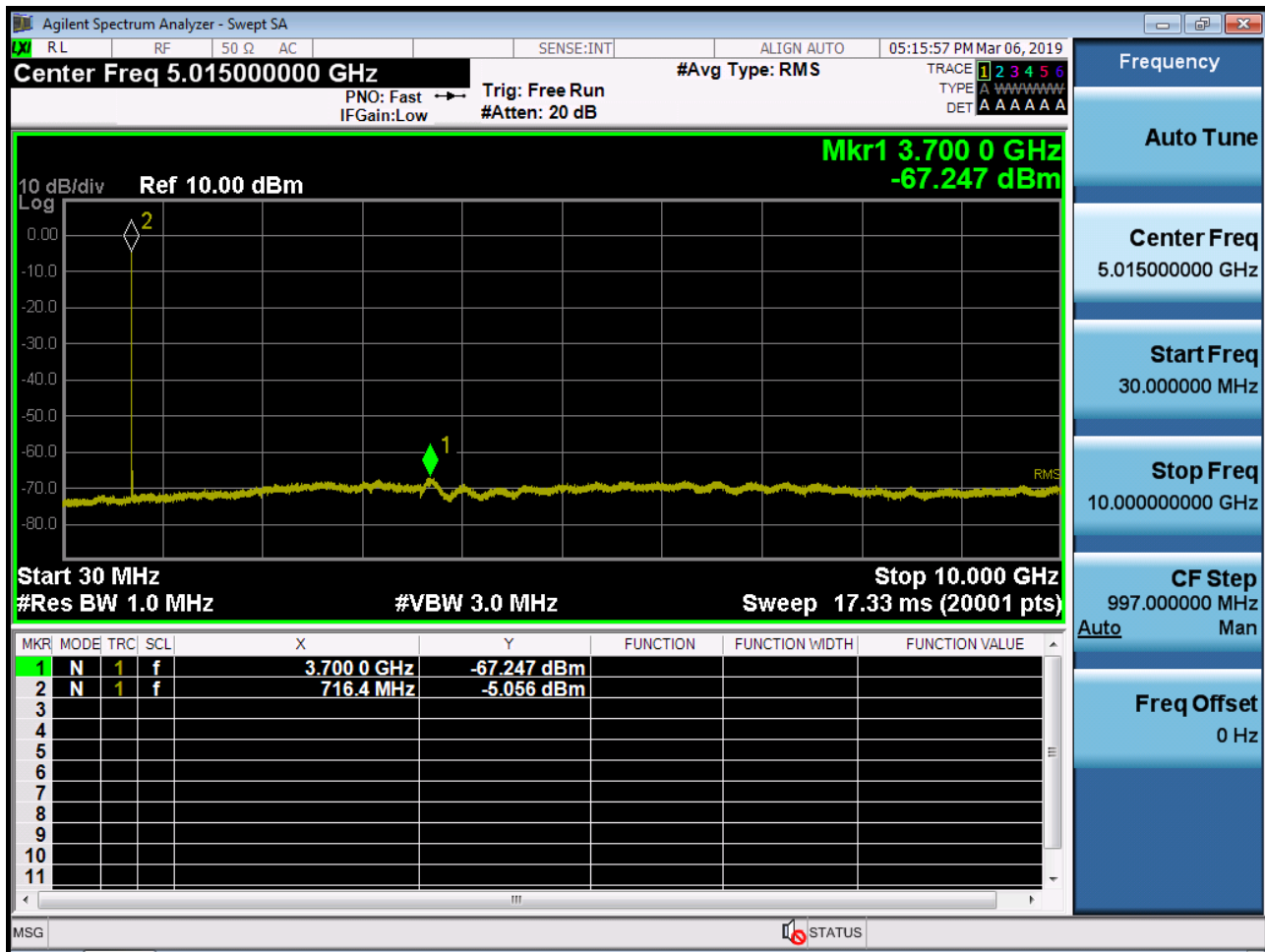
BAND 12. Conducted Spurious Plot _ (23017ch_1.4MHz_QPSK_RB 1_0)



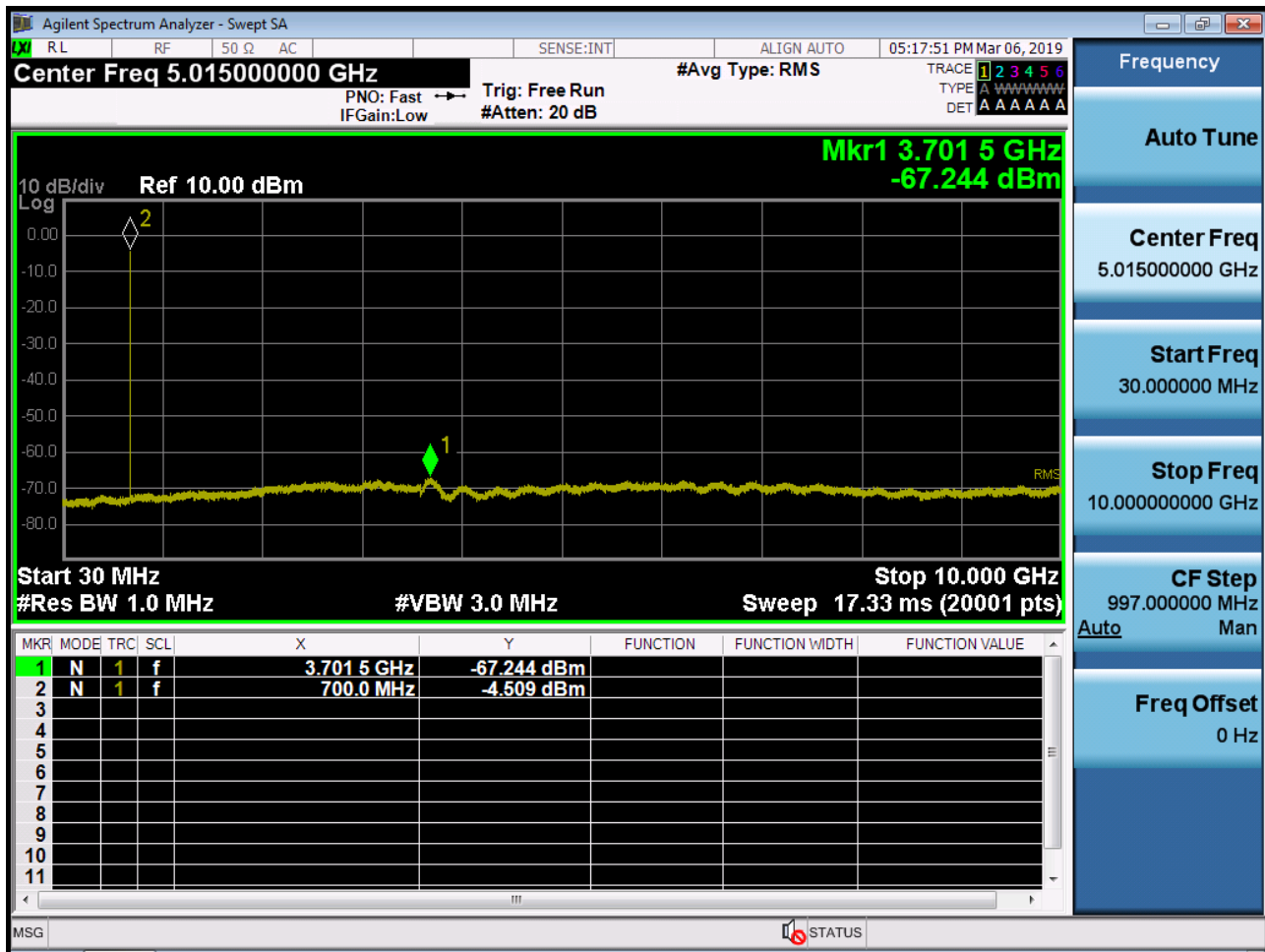
BAND 12. Conducted Spurious Plot _ (23095ch_1.4MHz_QPSK_RB 1_0)



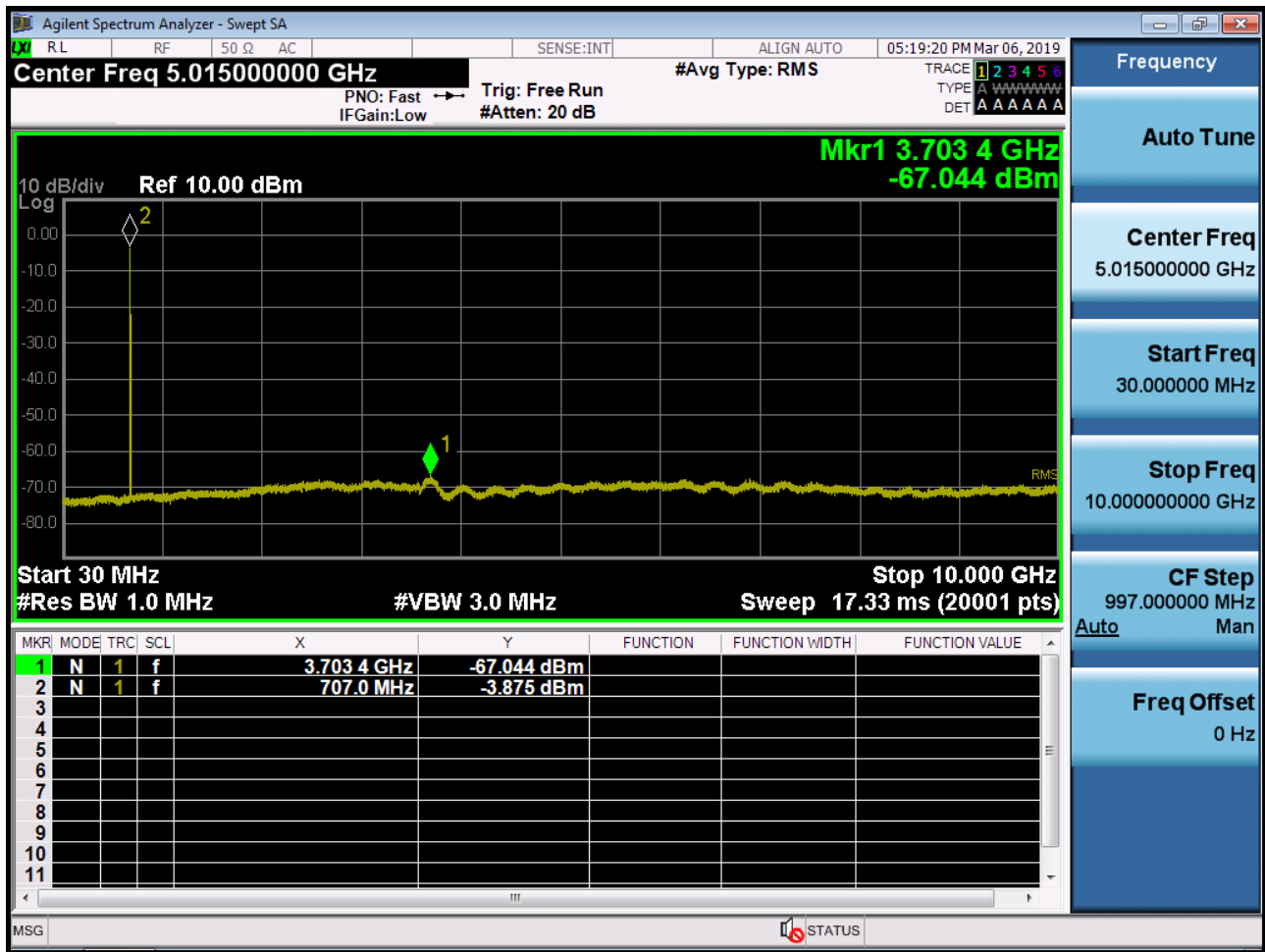
BAND 12. Conducted Spurious Plot _ (23173ch_1.4MHz_QPSK_RB 1_0)



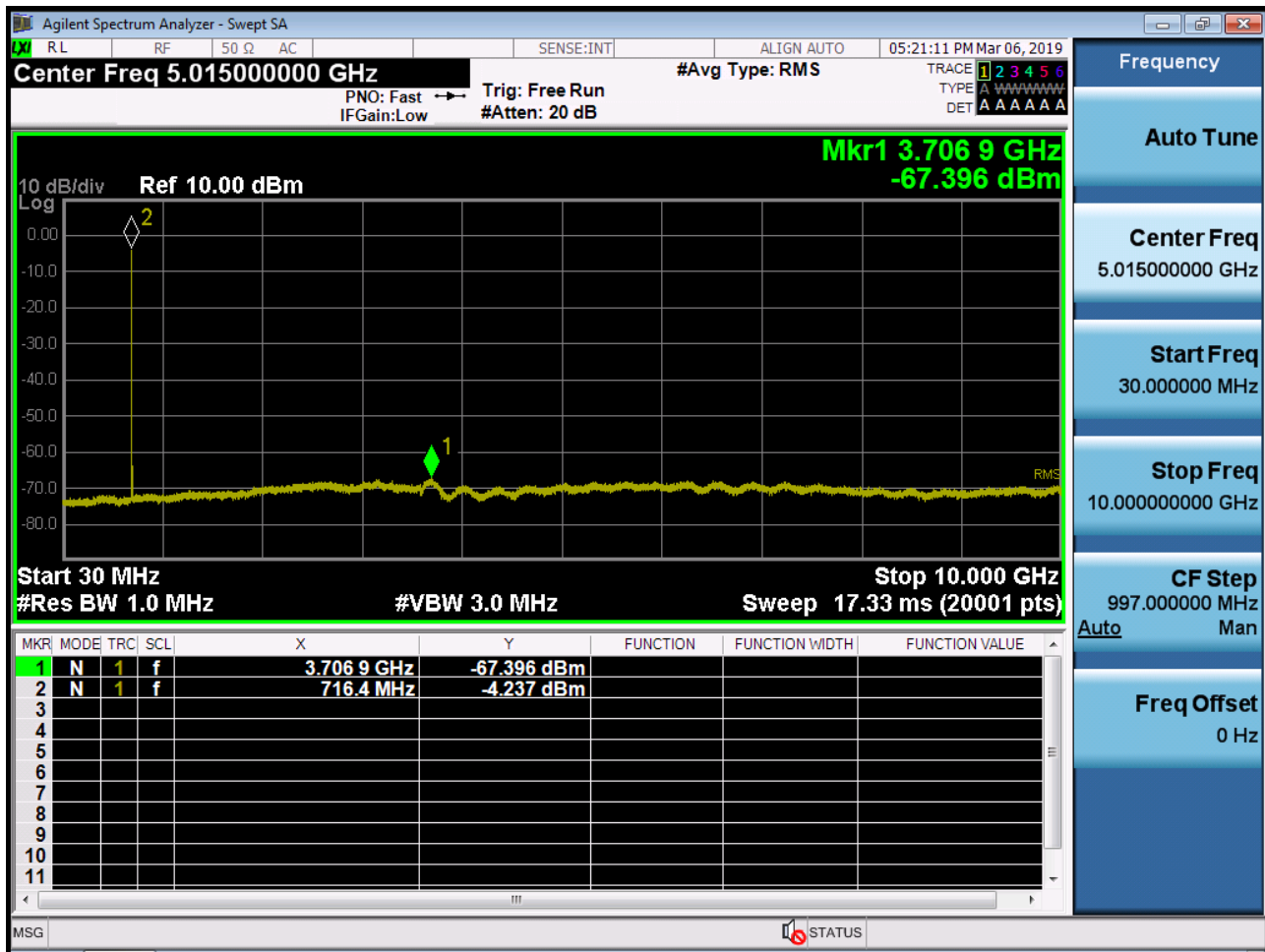
BAND 12. Conducted Spurious Plot _ (23025ch_3MHz_QPSK_RB 1_0)



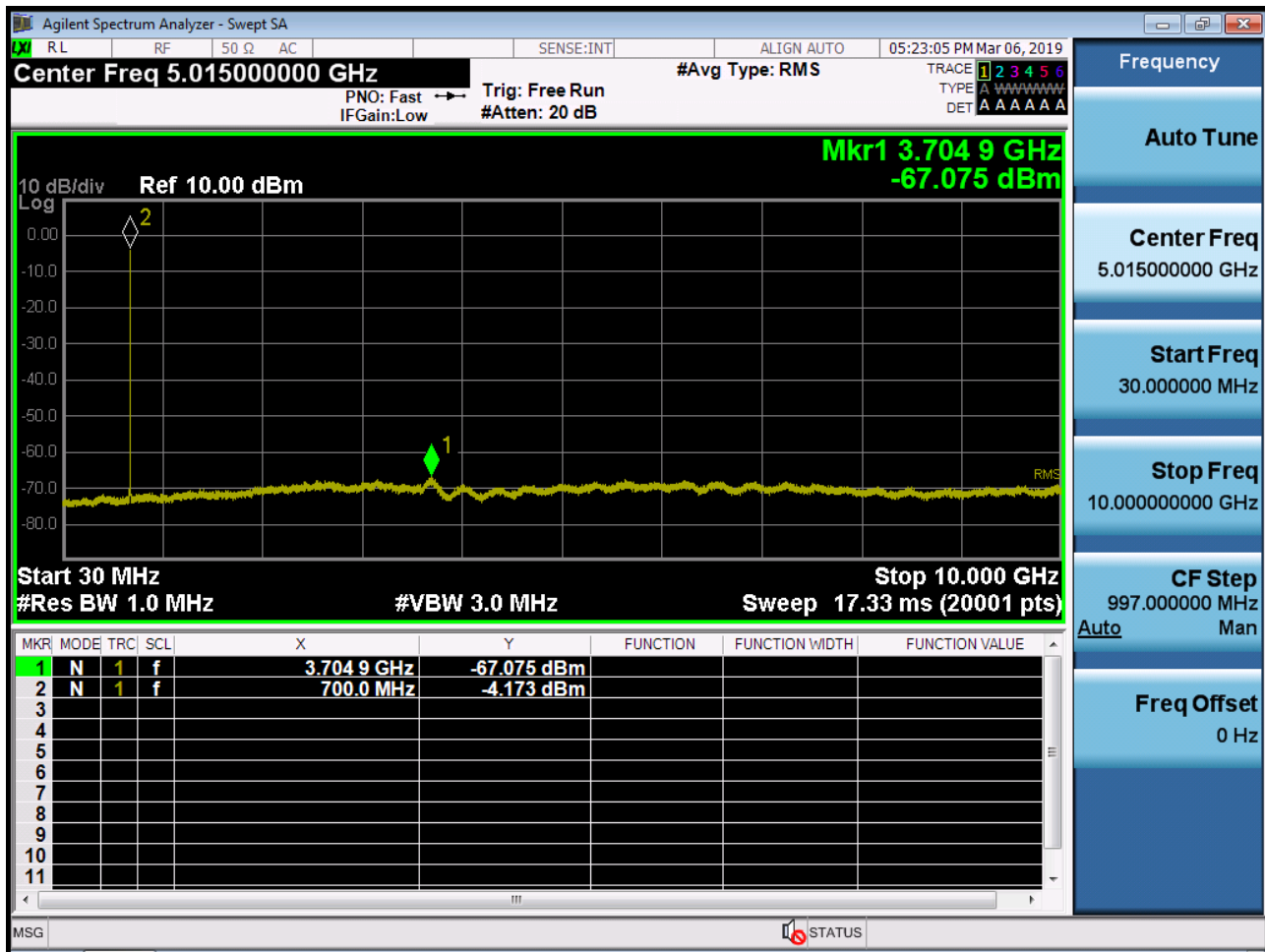
BAND 12. Conducted Spurious Plot _ (23095ch_3MHz_QPSK_RB 1_0)



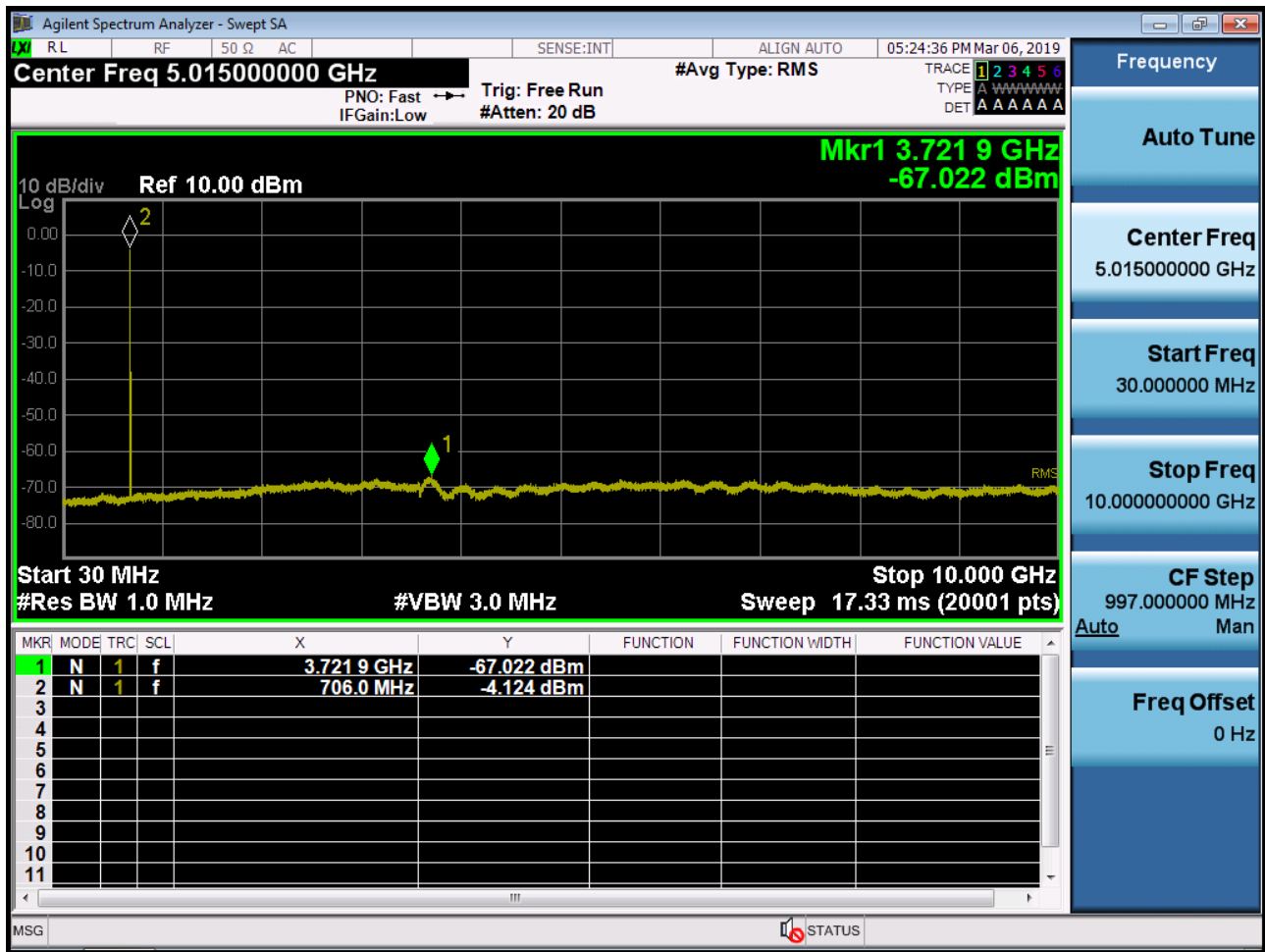
BAND 12. Conducted Spurious Plot _ (23165ch_3MHz_QPSK_RB 1_0)



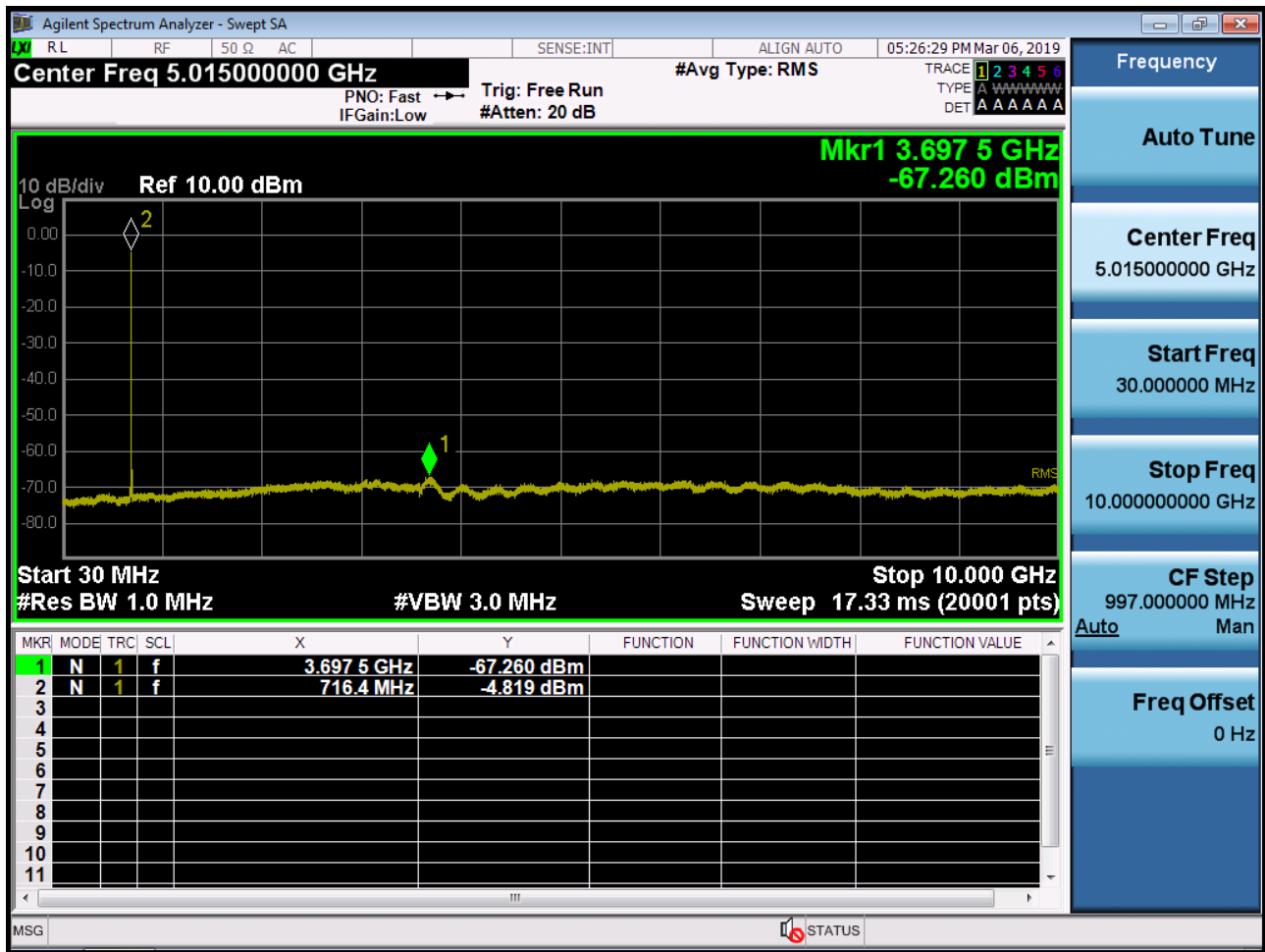
BAND 12 / 17. Conducted Spurious Plot _ (23035ch_5MHz_QPSK_RB 1_0)



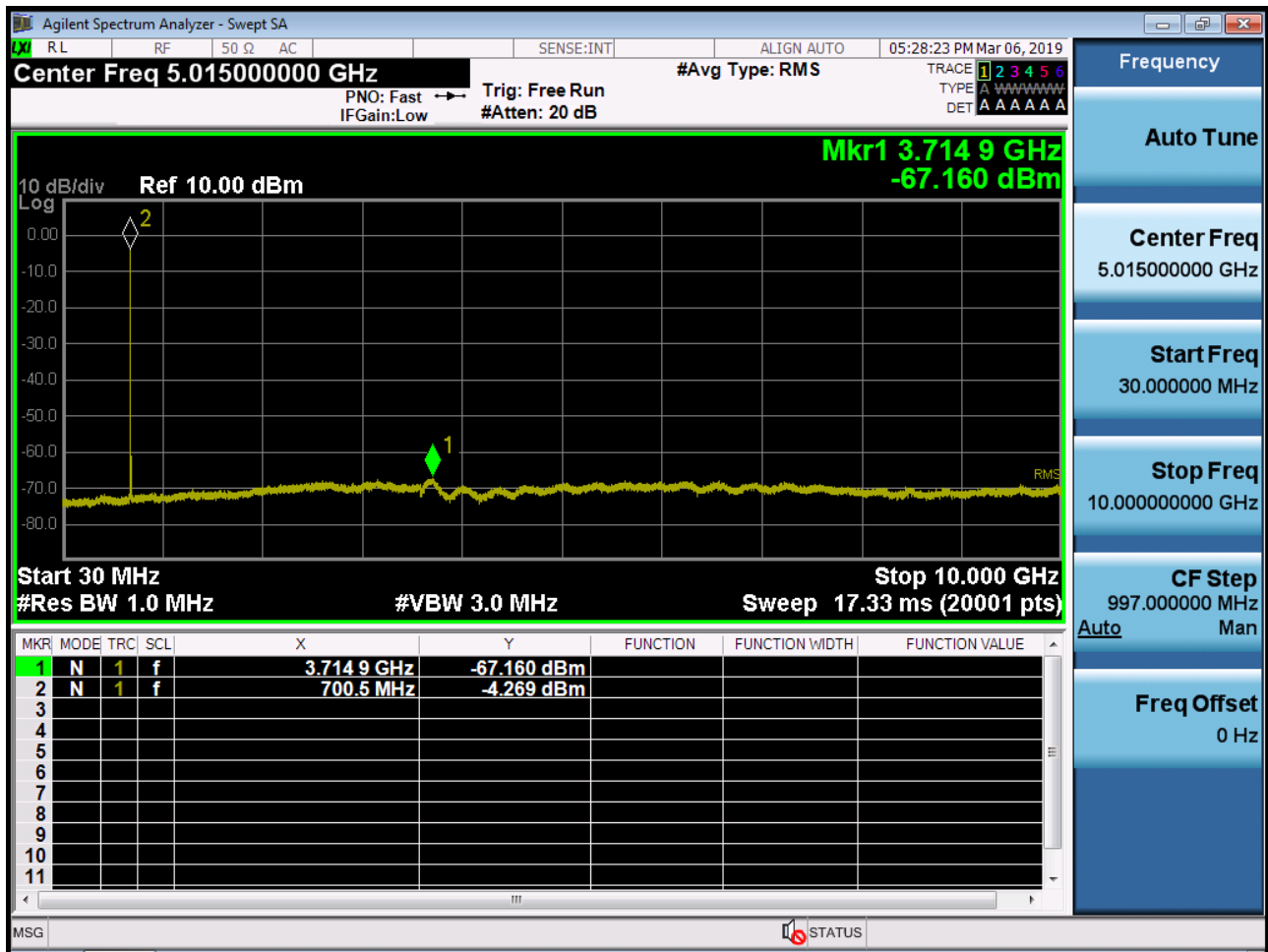
BAND 12 / 17. Conducted Spurious Plot _ (23095ch_5MHz_QPSK_RB 1_0)



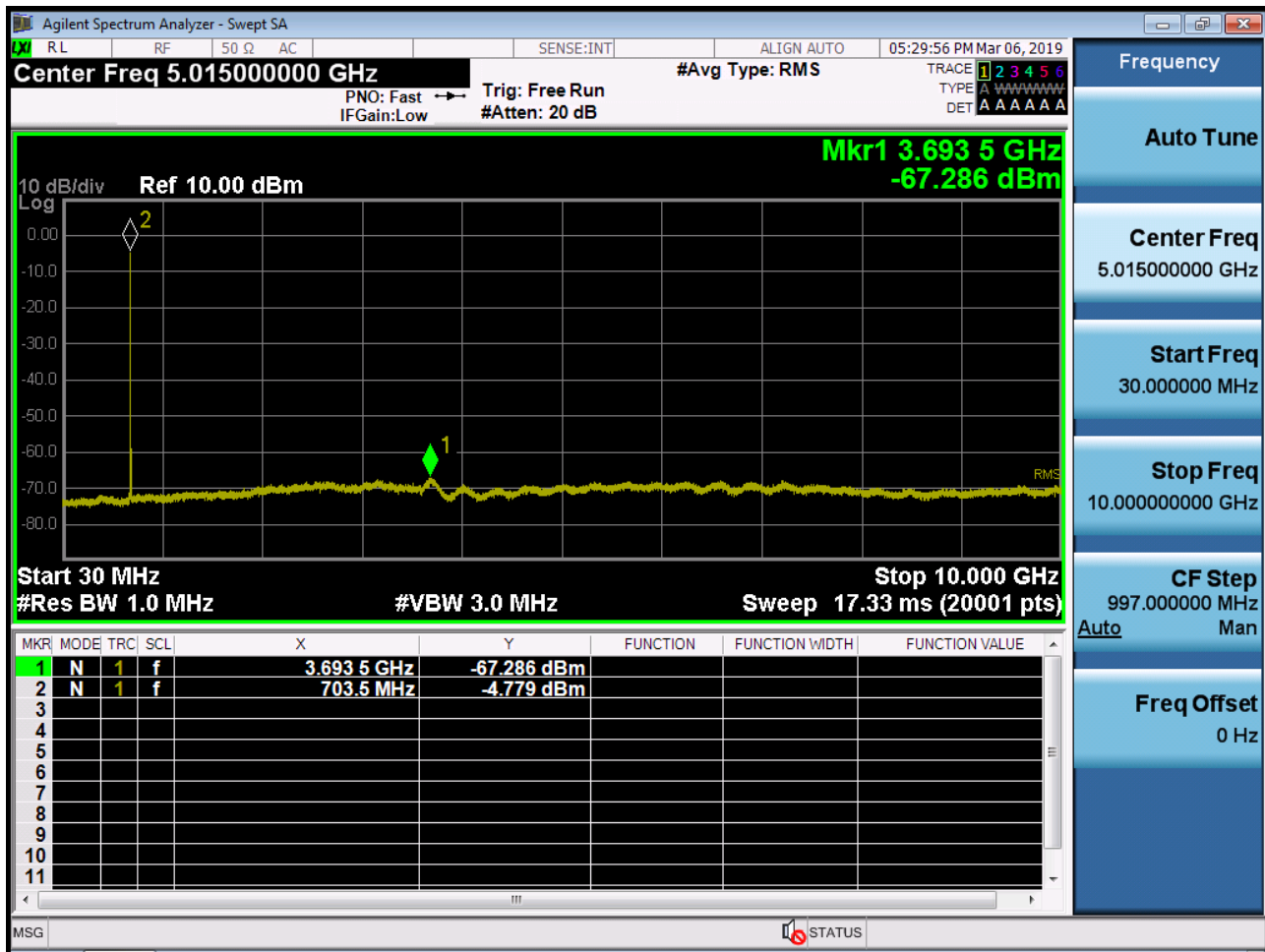
BAND 12 / 17. Conducted Spurious Plot _ (23155ch_5MHz_QPSK_RB 1_0)



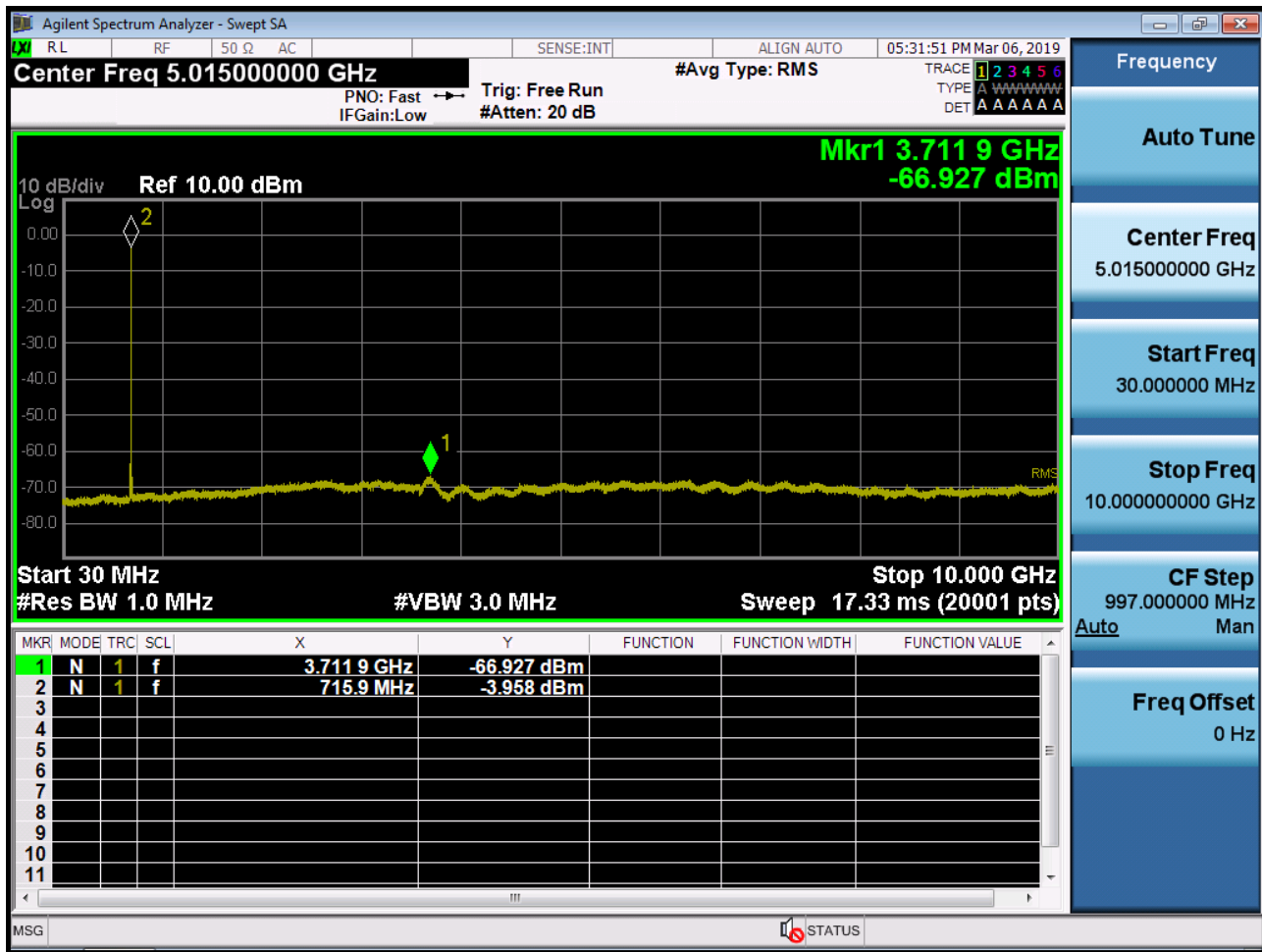
BAND 12 / 17. Conducted Spurious Plot _ (23060ch_10MHz_QPSK_RB 1_0)



BAND 12 / 17. Conducted Spurious Plot _ (23095ch_10MHz_QPSK_RB 1_0)



BAND 12 / 17. Conducted Spurious Plot _ (23130ch_10MHz_QPSK_RB 1_0)



10. ANNEX A_ TEST SETUP PHOTO

Please refer to test setup photo file no. as follows;

No.	Description
1	HCT-RF-1906-FC015-P